

# SmartFusion2 - Optimizing DDR Controller for Improved Efficiency - Libero SoC v11.7

## Table of Contents

|                                                           |    |
|-----------------------------------------------------------|----|
| Purpose . . . . .                                         | 1  |
| Introduction . . . . .                                    | 2  |
| References . . . . .                                      | 3  |
| Design Requirements . . . . .                             | 3  |
| Optimization Techniques . . . . .                         | 4  |
| Frequency of Operation . . . . .                          | 4  |
| Burst Length . . . . .                                    | 4  |
| AXI Master without Write Response State . . . . .         | 4  |
| Read Address Queuing . . . . .                            | 5  |
| Series of Writes or Reads . . . . .                       | 6  |
| DDR Configuration Tuning . . . . .                        | 6  |
| Implementation on the SmartFusion2 Device . . . . .       | 7  |
| Design Description . . . . .                              | 8  |
| Hardware Implementation . . . . .                         | 11 |
| Configuring the System Builder . . . . .                  | 12 |
| Simulation Using Micron DDR3 SDRAM Model . . . . .        | 18 |
| Simulation using Microsemi DDR3 SDRAM VIP Model . . . . . | 22 |
| Software Implementation . . . . .                         | 27 |
| Running the Design . . . . .                              | 29 |
| Board Jumper Settings . . . . .                           | 29 |
| Host PC to Board Connections . . . . .                    | 29 |
| USB Driver Installation . . . . .                         | 30 |
| Steps to Run the Design . . . . .                         | 30 |
| DDR3 SDRAM Bandwidth . . . . .                            | 33 |
| Conclusion . . . . .                                      | 35 |
| Appendix: Design Files . . . . .                          | 36 |
| List of Changes . . . . .                                 | 37 |

## Purpose

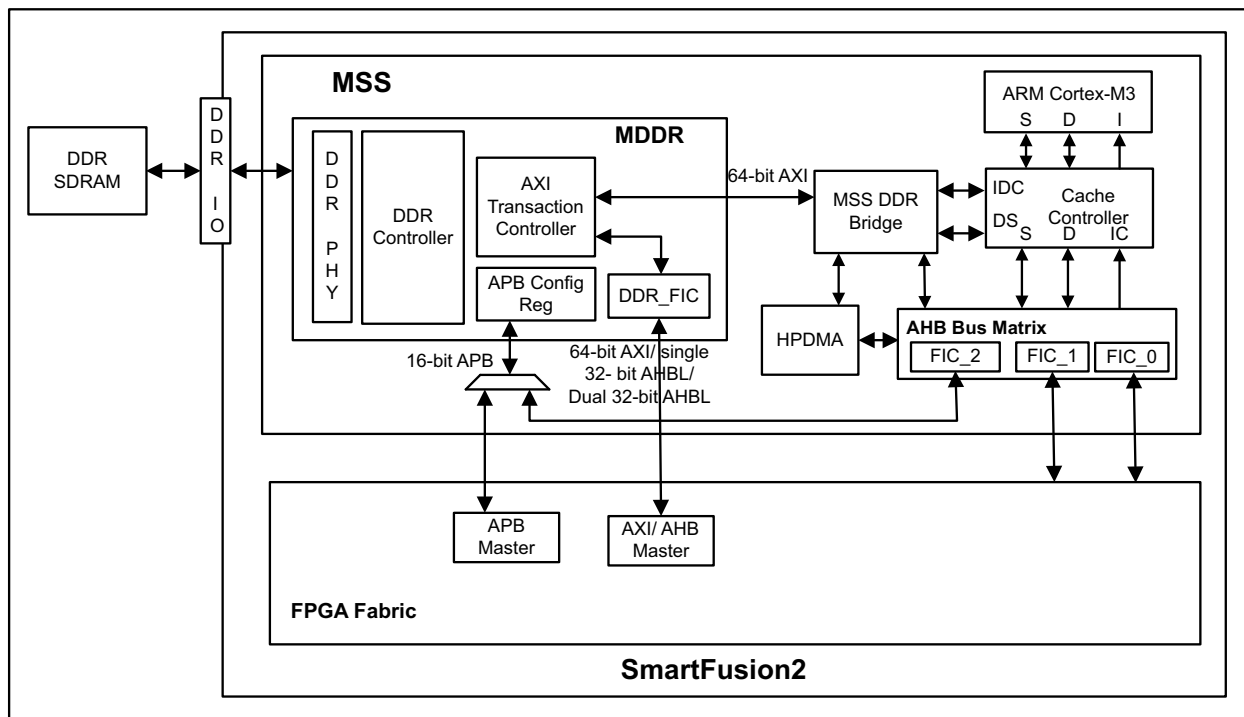
This application note describes the techniques for improving the efficiency of double data rate (DDR) controller using an example design for the SmartFusion<sup>®</sup>2 Advanced Development Kit board. It also provides details about implementing the DDR synchronous dynamic random access memory (SDRAM) simulation flow using the Micron<sup>®</sup> DDR3 SDRAM model and Microsemi DDR3 SDRAM verification IP (VIP) model.

## Introduction

The SmartFusion2 device has two high-speed hardened application-specific integrated circuit (ASIC) memory controllers such as microcontroller subsystem (MSS) DDR (MDDR) and fabric DDR (FDDR) for interfacing with the DDR2, DDR3, and low power DDR1 (LPDDR1) SDRAM memories. The MDDR and FDDR subsystems are used to access high-speed DDR memories for high-speed data transfer and code execution.

The DDR memory connected to the MDDR subsystem can be accessed by the MSS masters and the master logic implemented in the FPGA fabric master, whereas the DDR memory connected to the FDDR subsystem can be accessed only by an FPGA fabric master. The FPGA fabric masters communicate with the MDDR and FDDR subsystems through the AXI or AHB interfaces.

Figure 1 shows the MDDR data path for AXI/AHB interface.



**Figure 1 • MDDR Data Path for AXI/AHB Interfaces**

The AXI interface is used for burst transfers that provide an efficient access path and high throughput. Though the throughput is dependent on many system level parameters, it can be improved by applying specific optimization techniques. For more information on MDDR and FDDR subsystems, see the [UG0446: SmartFusion2 and IGLOO2 FPGA High Speed DDR Interfaces User Guide](#).

The sample design consists an AXI master, LSRAM, and counters for throughput measurement. During the write operation, the AXI master reads the LSRAM and writes to the DDR3 memory and measures the throughput. During the read operation, the AXI master reads the DDR3 memory and writes to LSRAM and measures the throughput. The throughput values are displayed on the host PC using the universal asynchronous receiver/transmitter (UART) interface.

Following are the types of memory simulation models that can be used:

- **Microsemi provided generic DDR memory simulation model (VIP):**  
The Libero® System-on-Chip (SoC) includes a JEDEC compliant VIP model. The VIP model is attached to the pin side of the MDDR/FDDR subsystem and simulates the functionality of a DDR memory device. It can be configured for the DDR2, DDR3, and LPDDR SDRAM memories and used to complement vendor models or to act as a substitute in case a vendor model is not available.
- **Vendor-specific memory model:** Memory vendors such as Micron, Samsung, and Hynix provide downloadable simulation models for specific memory devices. Ensure that the downloaded simulation model is JEDEC compliant.

This document also describes the DDR SDRAM simulation flow using the Micron DDR3 SDRAM and Microsemi DDR3 SDRAM VIP models.

## References

The following are the references:

- [UG0446: SmartFusion2 and IGLOO2 FPGA High Speed DDR Interfaces User Guide](#)
- [AC409: Connecting User Logic to AXI Interfaces of High-Performance Communication Blocks in the SmartFusion2 Devices Application Note](#)
- [AC333: Connecting User Logic to the SmartFusion Microcontroller Subsystem Application Note](#)
- [DDR Controller and Serial High Speed Controller Initialization Methodology](#)
- [UG0557: SmartFusion2 SoC FPGA Advanced Development Kit User Guide](#)

## Design Requirements

Table 1 lists the design requirements.

**Table 1 • Design Requirements**

| Design Requirements                                                                                                                                                                 | Description                         |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------|
| <b>Hardware Requirements</b>                                                                                                                                                        |                                     |
| SmartFusion2 Advanced Development Kit                                                                                                                                               | Rev B or later                      |
| Host PC or Laptop                                                                                                                                                                   | Any 64-bit Windows Operating System |
| <b>Software Requirements</b>                                                                                                                                                        |                                     |
| Libero SoC                                                                                                                                                                          | v11.7                               |
| SoftConsole                                                                                                                                                                         | v3.4 SP1*                           |
| <i>Note:</i> *For this application note, SoftConsole v3.4 SP1 is used. For using SoftConsole v4.0, see the <a href="#">TU0546: SoftConsole v4.0 and Libero SoC v11.7 Tutorial</a> . |                                     |

## Optimization Techniques

This section describes the following optimization techniques:

- Frequency of Operation
- Burst Length
- AXI Master without Write Response State
- Read Address Queuing
- Series of Writes or Reads
- DDR Configuration Tuning

### Frequency of Operation

The MDDR and FDDR subsystems support clock management dividers inside the embedded block. The divider ratios can be selected from the Clock Configurator for DDR clocks (MDDR\_CLK/FDDR\_CLK) and DDR\_FIC clock. The best overall throughput ratio is 2:1, that is, half the DDR clock frequency. Many other ratios are possible to provide flexibility to the FPGA design. To show the optimal data throughput, this application note shows all examples using the 2:1 ratio. The design example uses 64-bit AXI as an FPGA fabric interface and is configured to use 333.33 MHz as DDR clock frequency and 166.66 MHz as AXI clock. 166.66 MHz is the fastest clock frequency rate available to run the MDDR\_CLK, as this is the limit of the MSS CLK\_BASE.

### Burst Length

The MDDR and FDDR subsystems support the DRAM burst lengths of 4, 8, or 16, depending on the configured bus-width and the DDR type. The AXI transaction controller in the MDDR and FDDR subsystems supports up to 16-beat burst read and write. The AXI beat burst length (write and read) and burst length of DRAM affect the optimal performance, however, setting the maximum supported burst length for DDR SDRAM and AXI interface achieves the optimal performance. The design example uses a DDR SDRAM burst length of 8 and an AXI write and read beat burst length of 16.

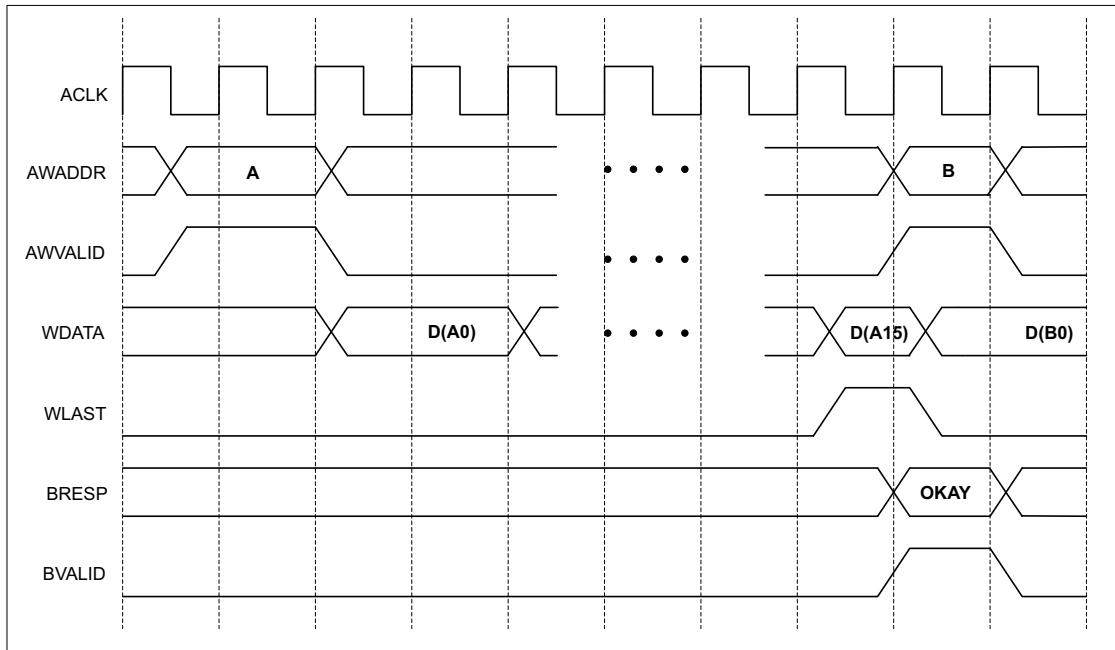
**Note:** The design example is designed to run on the SmartFusion2 Advanced Development Kit board, which has the SmartFusion2 M2S150 device and a DDR3 SDRAM from Micron with the part number; MT41K256M8DA -125. Both the devices support the maximum burst length of 8.

### AXI Master without Write Response State

When AXI master sends the last data (D (A15)), the WLAST signal goes HIGH, indicating that it is the last transfer in the first write burst. When AXI slave in DDR subsystem accepts all the data items, it drives a write response (BVALID) back to the master to indicate that the write transaction is complete. By AXI protocol, AXI master must wait for the write response before initiating the next write transaction. However, the time spent waiting for the write response reduces the overall throughput as the clock cycles are not used. AXI master can send the second burst write address (B) without waiting for the write response of the first burst. This improves the write throughput by decreasing the wait states.

This application note is focused on optimal throughput, and therefore, the write response channel is not verified. Microsemi recommends that when using this technique the write response channel is used concurrently with starting the next transfer to ensure that the previous write data is fully accepted. The AXI protocol has a defined methodology for handling the termination of write burst transaction. This must be followed if the write response channel returns an incorrect value.

Figure 2 shows the write transaction timing diagram without the write response state.

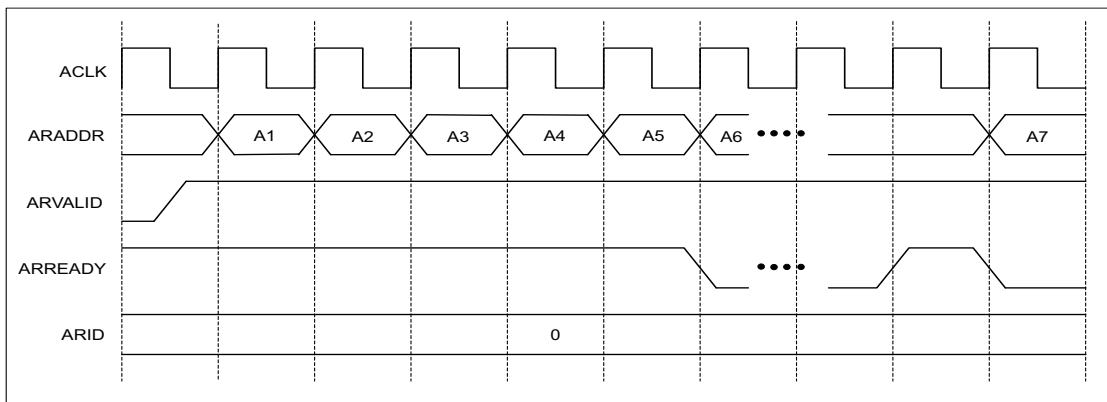


**Figure 2 • Write Transaction Timing Diagram without Write Response State**

## Read Address Queuing

The MDDR and FDDR subsystems support up to four outstanding read transactions. In 2:1 clock ratio, the MDDR controller starts the burst read transaction before the command FIFO full, which allows AXI master to send five burst read addresses.

Figure 3 shows the burst read address queuing timing diagram.



**Figure 3 • Read Transaction Timing Diagram with Burst Read Address Queuing**

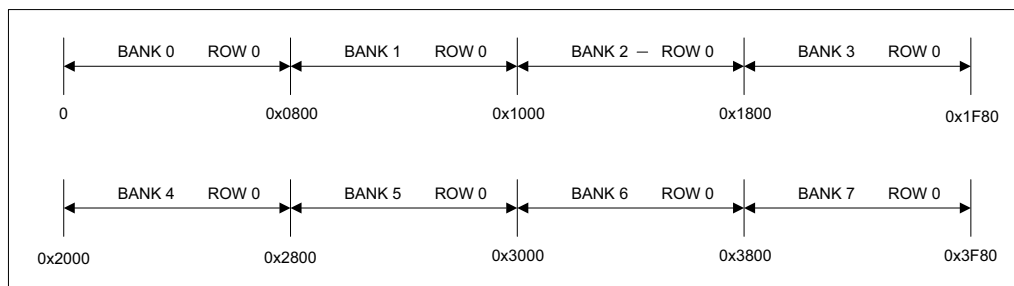
AXI master increments the burst read address as long as AXI slave in the DDR subsystem asserts the ARREADY signal. The burst read address queuing significantly increases the read throughput compared to the normal AXI read sequence. [Table 7 on page 34](#) and [Table 8 on page 35](#) show this significant improvement. Read address queuing does not reduce the initial latency associated with a DDR memory read access. By issuing multiple reads in sequence, the initial latency is only accounted for the first read. After the first read data is returned to the remainder of the requested data, the requested data is returned in sequence without a large read access penalty associated with the first read.

## Series of Writes or Reads

The MDDR and FDDR subsystems' performance depend on the method of data transfer between the DDR SDRAM and AXI master. The following methods of data transfer reduce optimal performance:

- Single beat burst read and write operation
- Random read and write operation
- Switching between read and write operation

The MDDR and FDDR subsystems' performance increase while performing a series of reads or writes from the same bank and row. [Figure 4](#) shows the AXI to DDR3 address mapping for the DDR3 SDRAM on the SmartFusion2 Advanced Development Kit board.



**Figure 4 • AXI to DDR3 Address Mapping**

When the AXI address crosses 0x0800, the DDR subsystem activates Row 0 of Bank 1. Row 1 of Bank 0 is activated only when the AXI address crosses 0x4000. If a new row is accessed every time, it must be pre-charged first. This means that additional time is needed before a row can be accessed and this reduces the overall throughput. Understanding the internal memory layout of the DDR and how it maps to the AXI address enables the accesses to minimize the row changes and increases the overall throughput.

## DDR Configuration Tuning

The DDR SDRAM datasheet provides the timing parameters required for the proper operation in terms of time units. These timings must match the configuration registers in the MDDR/FDDR controller. The timing parameters are required as number of DDR clock cycles and these are entered in the DDR configurator GUI. The selection of minimum write or read delay values can result in optimal performance. Implementing this approach requires extensive memory testing to ensure that the memory transfers are stable.

The SmartFusion2 Advanced Development Kit DDR3 is supplied with a default configuration file to setup the MDDR controller, which is available on its documentation web page.

Table 2 lists the tuned parameters for better performance than the values in the default configuration file.

**Table 2 • Tuned DDR Timing Parameters**

| Parameters | Default Values | Tuned Values |
|------------|----------------|--------------|
| CAS        | 6 (CLK)        | 5            |
| RAS min    | 15             | 12           |
| RAS max    | 8192           | 22528        |
| RCD        | 6 (CLK)        | 5            |
| RP         | 7 (CLK)        | 5            |
| REFI       | 3104           | 2592         |
| RC         | 51             | 17           |
| RFC        | 79             | 54           |
| WR         | 6              | 5            |
| FAW        | 32             | 10           |

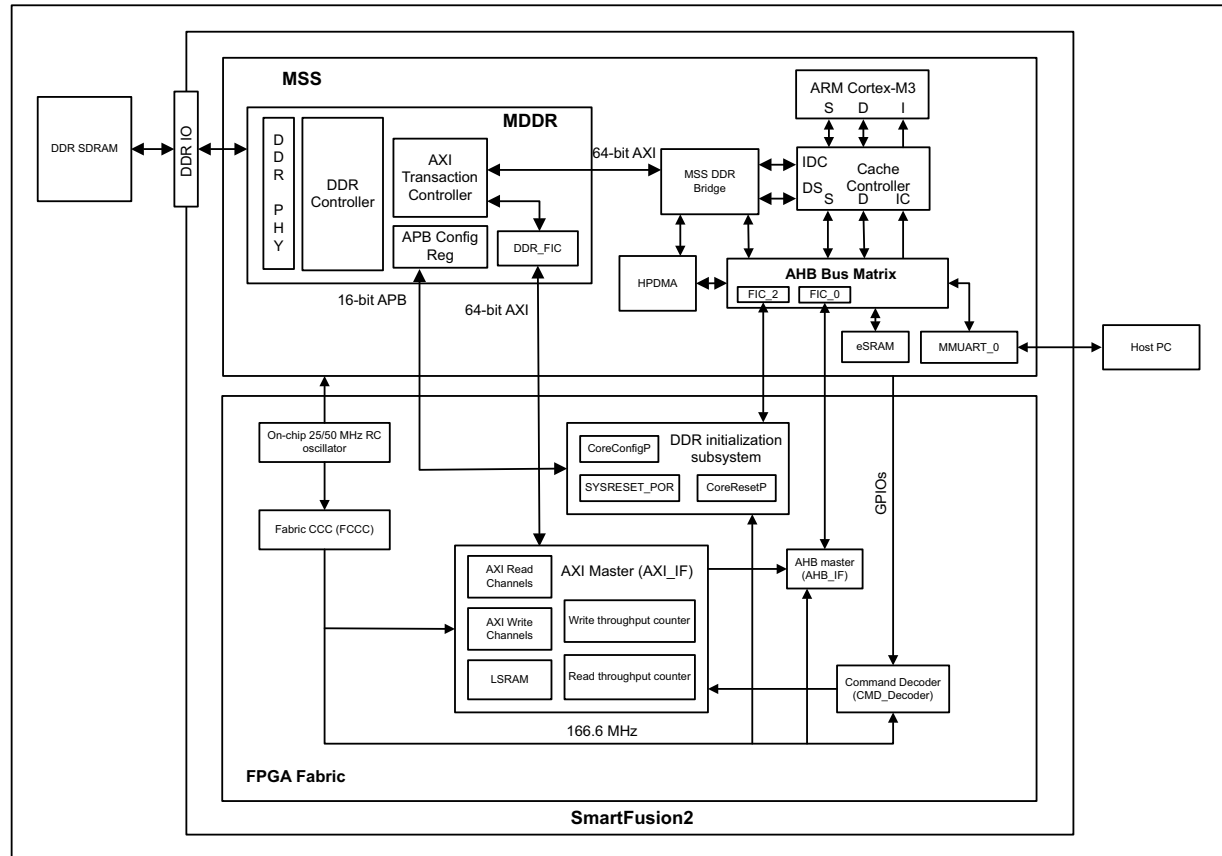
## Implementation on the SmartFusion2 Device

The optimization techniques that are mentioned in the preceding section are implemented and validated using the SmartFusion2 Advanced Development Kit board. This section describes the following:

- [Design Description](#)
- [Hardware Implementation](#)
- [Software Implementation](#)
- [Running the Design](#)

## Design Description

The design consists MSS, CoreConfigP IP, CoreResetP IP, SYSRESET\_POR Macro, on-chip 25/50 MHz RC oscillator, Fabric CCC (FCCC), AXI master (AXI\_IF), AHB master (AHB\_IF), and a command decoder (CMD\_Decoder). [Figure 5](#) shows the block diagram of the design.



**Figure 5 • Top-Level Block Diagram of the Design**

MSS is configured to use one UART interface (MMUART\_0), MSS clock conditioning circuit (MSS\_CCC), RESET Controller, eight GPIOs, one instance of the fabric interface (FIC\_0), FIC\_2 (Peripheral Initialization), and MDDR.

The FIC\_0 interface is configured to use a slave interface with the AHB-Lite (AHBL) interface type. The FIC\_2 is configured to initialize the MSS DDR using the ARM® Cortex®-M3 processor along with the CoreConfigP, CoreResetP, and SYSRESET\_POR macro. The MMUART\_0 is used as an interface for writing to HyperTerminal. Eight GPIOs are configured as output and routed to the FPGA fabric. The Cortex-M3 processor initiates the AXI write and read operation using these GPIOs. The MDDR is configured to use the DDR3 interface and routes the AXI interface to the FPGA fabric.

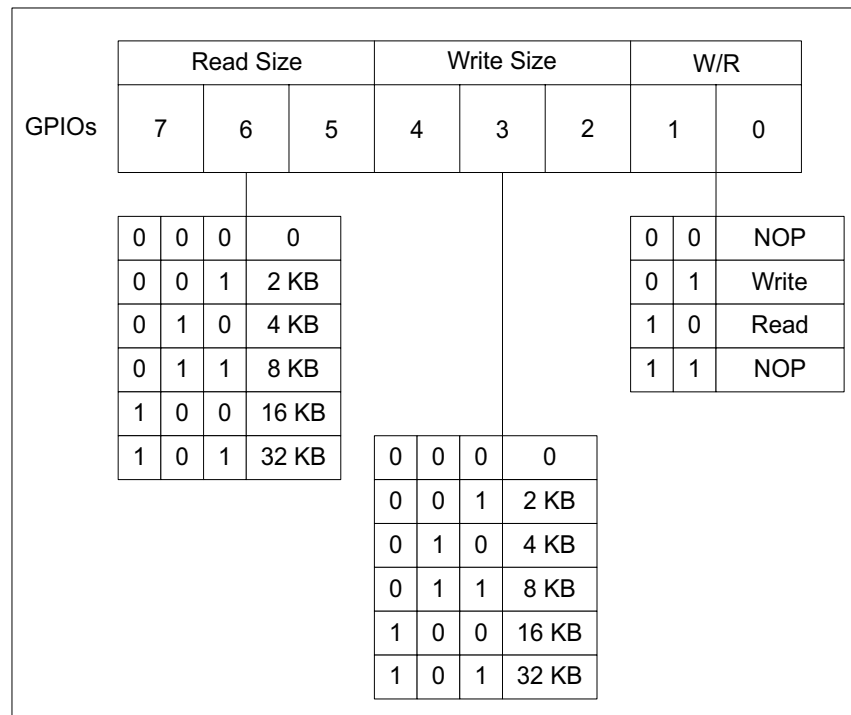
FCCC is configured to provide the 166.6 MHz reference clock to the MSS\_CCC and the fabric logic. The on-chip 25 MHz/50 MHz RC oscillator is the reference clock source for the FCCC.

Table 3 lists the MSS\_CCC generated clocks.

**Table 3 • MSS\_CCC Generated Clocks**

| Clock Name      | Frequency in MHz |
|-----------------|------------------|
| M3_CLK          | 166.6            |
| MDDR_CLK        | 333.2            |
| DDR_SMC_FIC_CLK | 166.6            |
| APB_0           | 83.3             |
| APB_1           | 83.3             |
| FIC_0_CLK       | 166.6            |

The command decoder receives the AXI transaction control from the Cortex-M3 processor through GPIOs and generates write, read, write size, and read size signals. Figure 6 shows the command decoding.



**Figure 6 • Command Decoding**

AXI master block consists AXI read channel, AXI write channel, write throughput counter, read throughput counter, and 512x64 LSRAM. It performs the write or read operation<sup>1</sup> based on the input signals from the command decoder. During the write operation, AXI master reads the LSRAM and writes into the DDR3 memory, and then measures the write throughput. During the read operation, AXI master reads the DDR3 memory and writes into LSRAM, and then measures the read throughput. The write throughput counter counts the AXI clocks between AWWVALID of first data and WLAST of last data. Similarly, the read throughput counter counts the AXI clocks between ARVALID of first data and RLAST of last data. After triggering the write or read operation, the AXI master performs the write or read operation eight times to get the average throughput. During the write operation, the write address (AWADDR) starts from 0x00000000, and is incremented by 128 (16-beat burst). During the read operation, the read address (ARADDR) starts from 0x01000000, and is incremented by 128.

After each write or read operation, AXI master sends the throughput count value and an eSRAM address starting from 0x20008104 to AHBL master. Then, AHBL master writes the throughput values into eSRAM. After that the Cortex-M3 processor reads the values and sends to the host PC using the UART interface.

For more information on creating a custom AXI interface on user logic, see the [AC409: Connecting User Logic to AXI Interfaces of High-Performance Communication Blocks in the SmartFusion2 Devices Application Note](#).

For more information on creating a custom AHB interface on user logic, see the [AC333: Connecting User Logic to the SmartFusion Microcontroller Subsystem Application Note](#).

For more information on timing optimization performed in the AXI interface, see the [UG0446: SmartFusion2 and IGLOO2 FPGA High Speed DDR Interfaces User Guide](#).

---

1. The write or read operation depends on the size of write or read data. For example, if the write size is selected as 2 KB, then one AXI write operation equals to 16x16-beat burst (16x16x64).

## Hardware Implementation

The hardware implementation involves:

- Configuring the System Builder
- Connecting with a user logic AXI master (AXI\_IF), AHB master (AHB\_IF), and a command decoder (CMD\_Decoder)

Figure 7 shows the top-level SmartDesign of the example design.

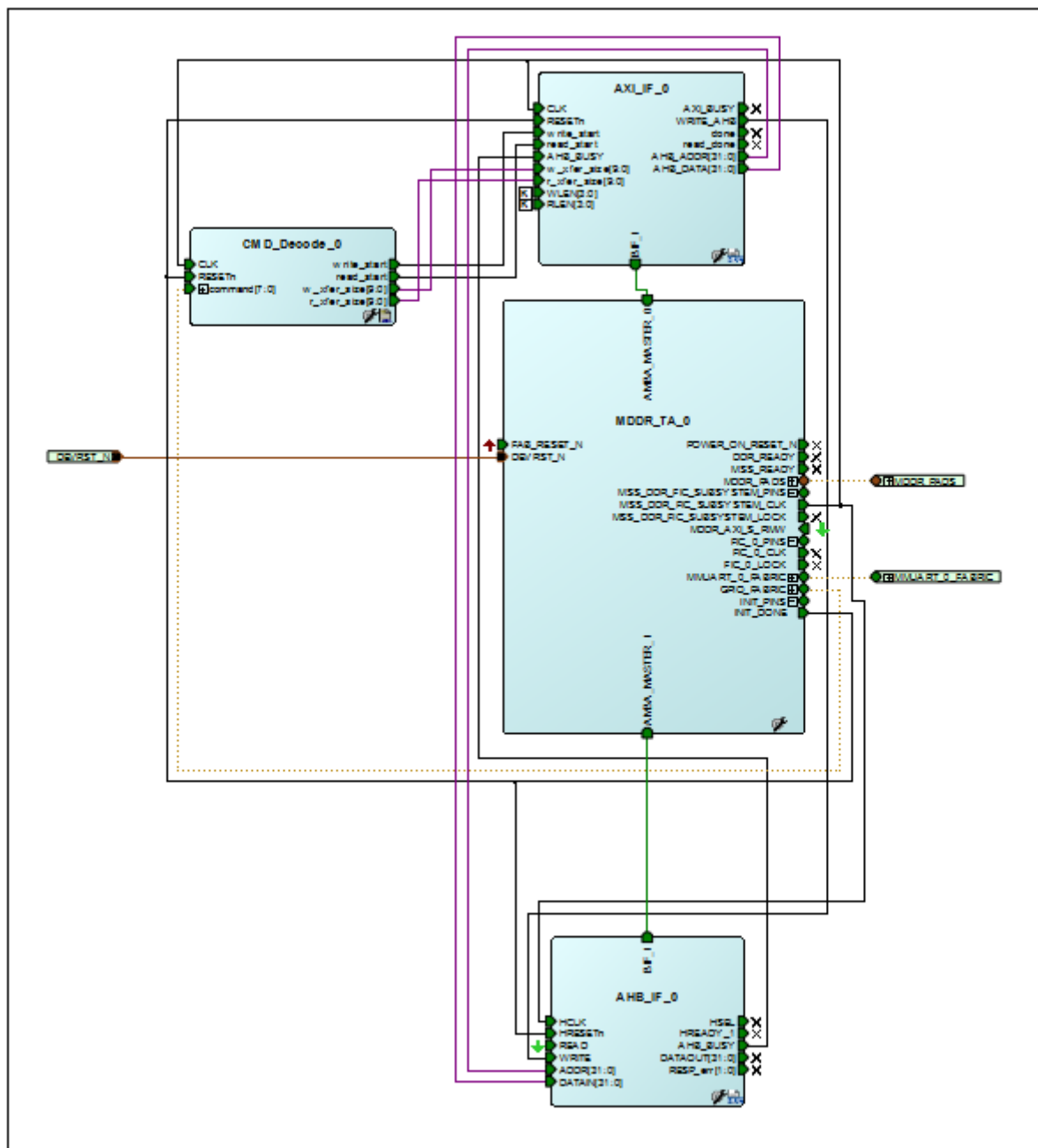


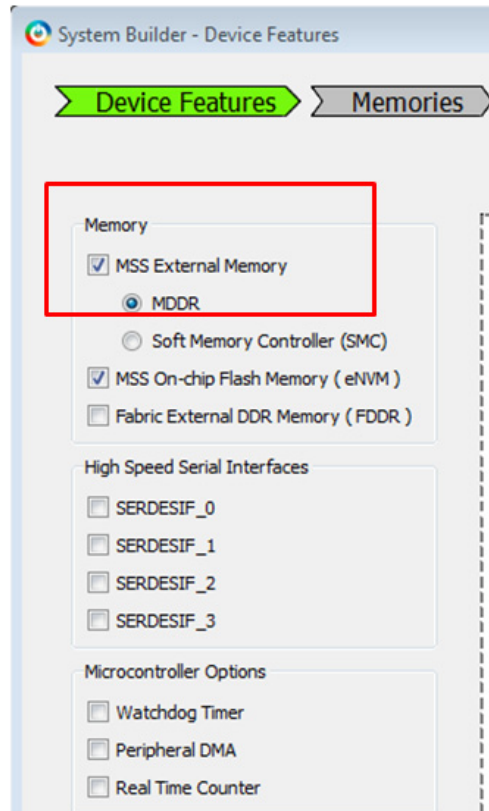
Figure 7 • Top-Level SmartDesign

## Configuring the System Builder

This section describes how to configure the MDDR and other device features and then build a complete system using the System Builder graphical design wizard in the Libero SoC software. For more information on how to launch and use the System Builder wizard, see the [SmartFusion2 System Builder User Guide](#).

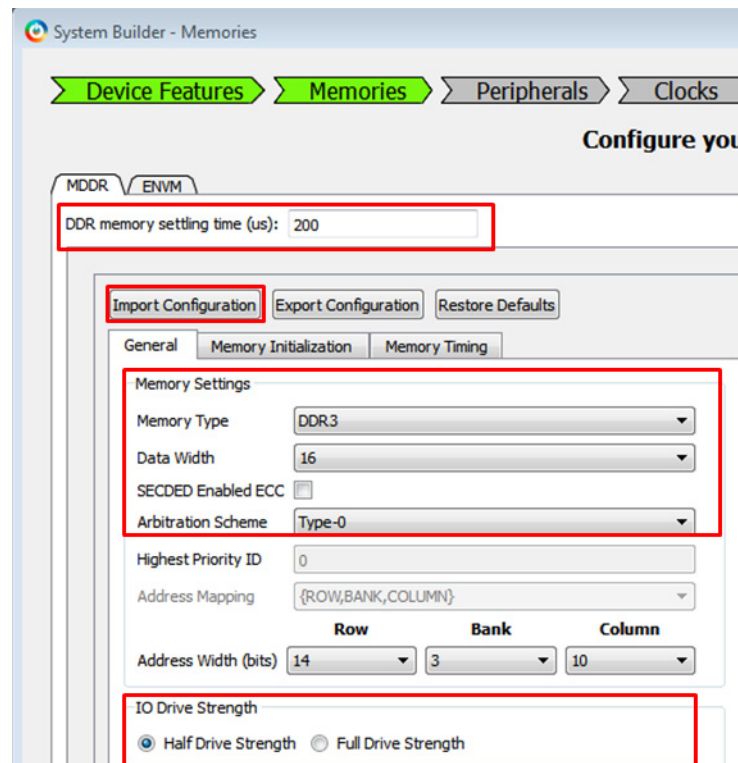
The following steps describe how to configure the MDDR and access it from AXI master in the FPGA fabric:

1. Go to the **System Builder - Device Features** tab and select the **MDDR** check box. Leave the rest of the check boxes unchecked, as shown in [Figure 8](#).



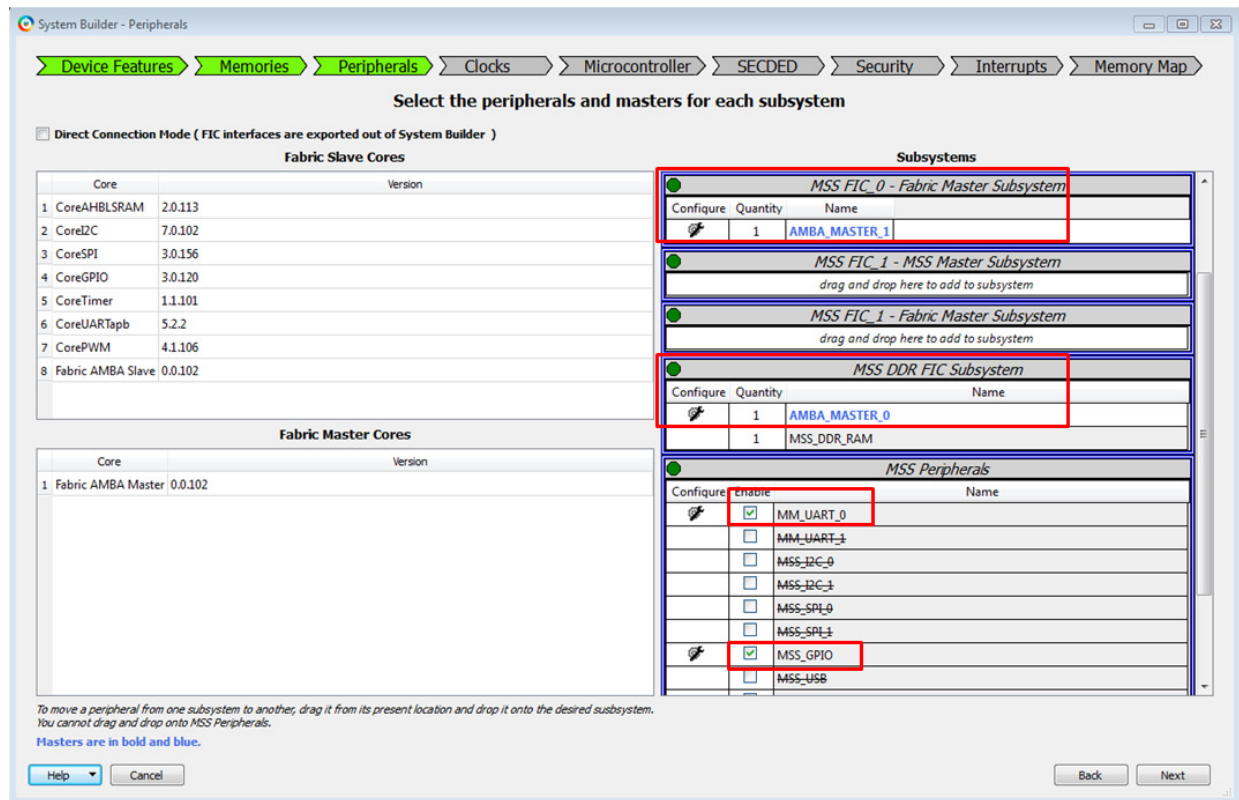
**Figure 8 • System Builder - Device Features Tab**

2. Configure the MDDR in **Memories** tab as shown in [Figure 9](#). In this example, the design is created to access the DDR3 memory with a 16-bit data width and no ECC.
3. Set the DDR memory settling time to 200  $\mu$ s and click **Import Configuration** file to initialize the DDR memory. The configuration file is stored in eNVM. The MDDR subsystem registers must be initialized before accessing DDR memory through the MDDR subsystem. The MDDR configuration register file is provided along with the design file (See ["Appendix: Design Files"](#) on [page 36](#)).



**Figure 9 • Memory Configuration**

- In the Peripherals tab, drag **Fabric AMBA Master** to **MSS DDR FIC Subsystem**, as shown in Figure 10. **AMBA\_MASTER\_0** is added to the subsystem. Configure the Interface Type as **AXI**. Figure 10 shows the Peripherals tab.



**Figure 10 • Selecting MMUART\_0 and MSS GPIO in Peripherals Tab**

- Drag **Fabric AMBA Master** to **MSS FIC\_0 - Fabric Master Subsystem**. **AMBA\_MASTER\_1** is added to the subsystem and configured with AHBLite.
- Under **MSS Peripherals**, select **MM\_UART\_0** and **MSS\_GPIO**.

7. Select **IO** under **Connect To** option in the **MM\_UART\_0 Configuration** window, as shown in Figure 11.

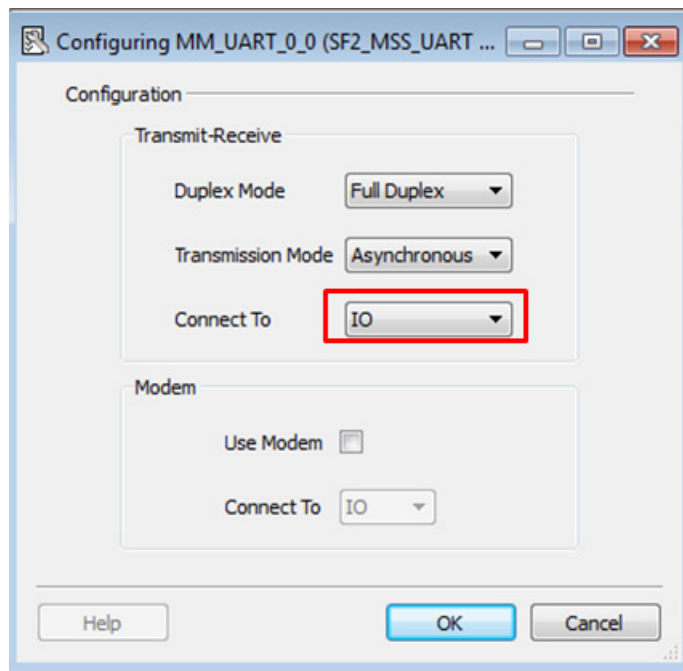
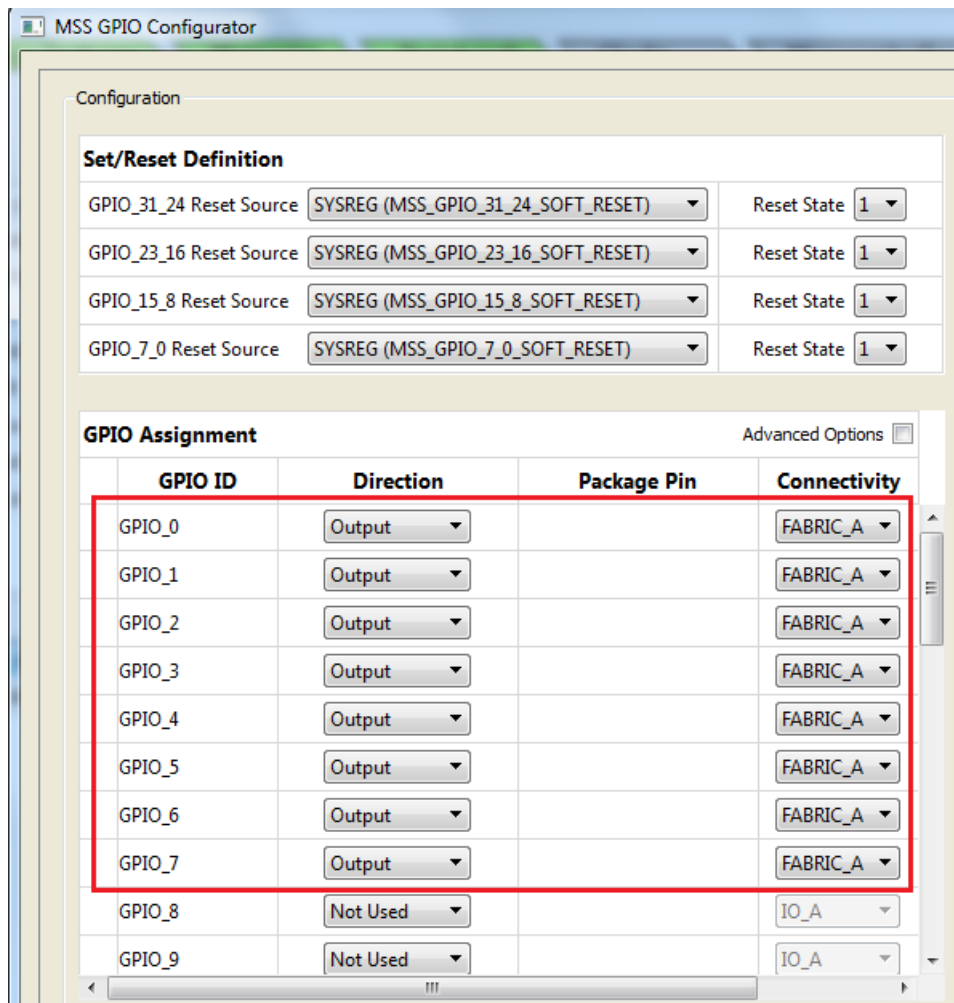


Figure 11 • MM\_UART\_0 Configuration Window

8. Use the settings in the **MSS\_GPIO Configurator** tab, as shown in [Figure 12](#) and keep the remaining at default state. Eight GPIOs are configured as output and routed to the FPGA fabric.



**MSS\_GPIO Configurator**

Configuration

**Set/Reset Definition**

|                         |                                    |             |   |
|-------------------------|------------------------------------|-------------|---|
| GPIO_31_24 Reset Source | SYSREG (MSS_GPIO_31_24_SOFT_RESET) | Reset State | 1 |
| GPIO_23_16 Reset Source | SYSREG (MSS_GPIO_23_16_SOFT_RESET) | Reset State | 1 |
| GPIO_15_8 Reset Source  | SYSREG (MSS_GPIO_15_8_SOFT_RESET)  | Reset State | 1 |
| GPIO_7_0 Reset Source   | SYSREG (MSS_GPIO_7_0_SOFT_RESET)   | Reset State | 1 |

**GPIO Assignment** Advanced Options ☐

| GPIO ID | Direction | Package Pin | Connectivity |
|---------|-----------|-------------|--------------|
| GPIO_0  | Output    |             | FABRIC_A     |
| GPIO_1  | Output    |             | FABRIC_A     |
| GPIO_2  | Output    |             | FABRIC_A     |
| GPIO_3  | Output    |             | FABRIC_A     |
| GPIO_4  | Output    |             | FABRIC_A     |
| GPIO_5  | Output    |             | FABRIC_A     |
| GPIO_6  | Output    |             | FABRIC_A     |
| GPIO_7  | Output    |             | FABRIC_A     |
| GPIO_8  | Not Used  |             | IO_A         |
| GPIO_9  | Not Used  |             | IO_A         |

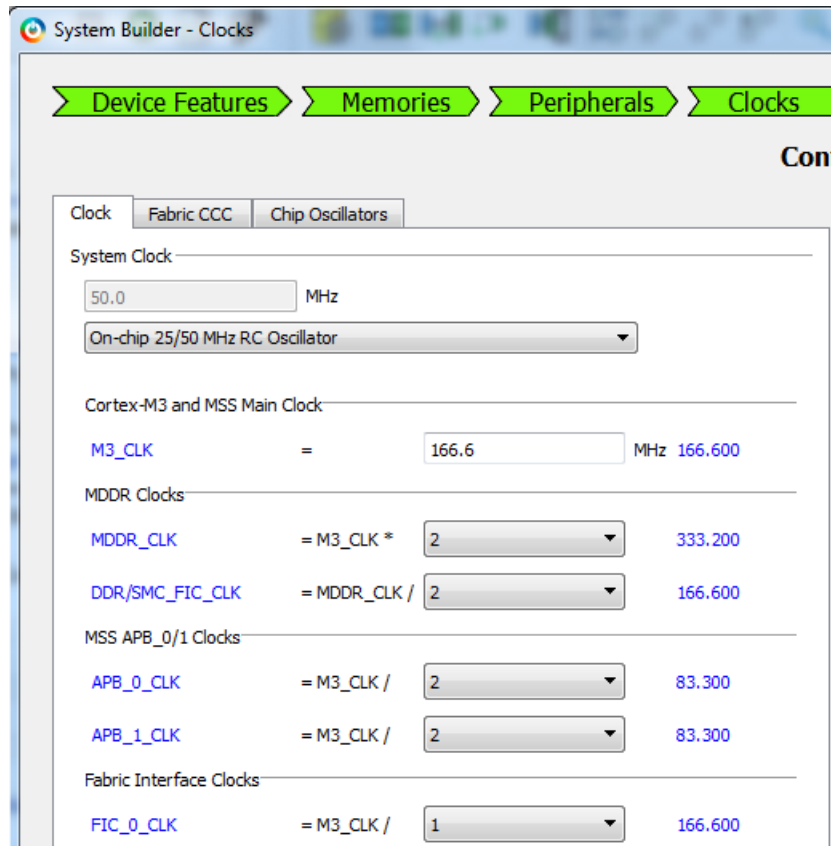
**Figure 12 • MSS GPIO Configuration**

9. Configure the System clock and Subsystem clocks in the **Clocks** tab, as listed in [Table 4](#).

**Table 4 • System and Subsystem Clocks**

| Clock Name      | Frequency in MHz                    |
|-----------------|-------------------------------------|
| System clock    | On-chip 25 MHz/50 MHz RC oscillator |
| M3_CLK          | 166.6                               |
| MDDR_CLK        | 333.2                               |
| DDR/SMC_FIC_CLK | 166.6                               |
| APB_0_CLK       | 83.3                                |
| APB_1_CLK       | 83.3                                |
| FIC_0_CLK       | 166.6                               |

Figure 13 shows the **Clocks** configuration window.



**Figure 13 • System and Subsystem Clocks Configuration**

10. Follow the remaining steps with default settings and generate the design.
11. Instantiate the custom logic (AXI master, AHB master, and a command decoder) and connect, as shown in [Figure 7 on page 11](#).

## Simulation Using Micron DDR3 SDRAM Model

### Setting Up the Simulation Model

Setting up and running the simulation involve the following steps:

1. Obtain the Micron DDR3 memory model files - the SmartFusion2 Advanced Development Kit board has the DDR3 SDRAM from Micron with the part number; MT41K256M8DA -125. The memory model used in the example design supports this device (See "Appendix: Design Files" on page 36).
2. Copy the `ddr3.v` and `ddr3_parameters.vh` simulation model files to the `\<Libero SoC project directory>\stimulus` directory.
3. Instantiate and connect the DDR3 memory model in the testbench, as shown in Figure 14.

---

```

ddr3 DDR3_0 (
    .rst_n(MDDR_RESET_N),
    .ck(MDDR_CLK),
    .ck_n(MDDR_CLK_N),
    .cke(MDDR_CKE),
    .cs_n(MDDR_CS_N),
    .ras_n(MDDR_RAS_N),
    .cas_n(MDDR_CAS_N),
    .we_n(MDDR_WE_N),
    .addr(MDDR_ADDR[14:0]),
    .ba(MDDR_BA),
    .dm_tdq(MDDR_DM_RDQS[0]),
    .dq(MDDR_DQ[7:0]),
    .dqs(MDDR_DQS[0]),
    .dqs_n(MDDR_DQS_N[0]),
    .odt(MDDR_ODT),
    .tdqs_n()
);

ddr3 DDR3_1 (
    .rst_n(MDDR_RESET_N),
    .ck(MDDR_CLK),
    .ck_n(MDDR_CLK_N),
    .cke(MDDR_CKE),
    .cs_n(MDDR_CS_N),
    .ras_n(MDDR_RAS_N),
    .cas_n(MDDR_CAS_N),
    .we_n(MDDR_WE_N),
    .addr(MDDR_ADDR[14:0]),
    .ba(MDDR_BA),
    .dm_tdq(MDDR_DM_RDQS[1]),
    .dq(MDDR_DQ[15:8]),
    .dqs(MDDR_DQS[1]),
    .dqs_n(MDDR_DQS_N[1]),
    .odt(MDDR_ODT),
    .tdqs_n()
);

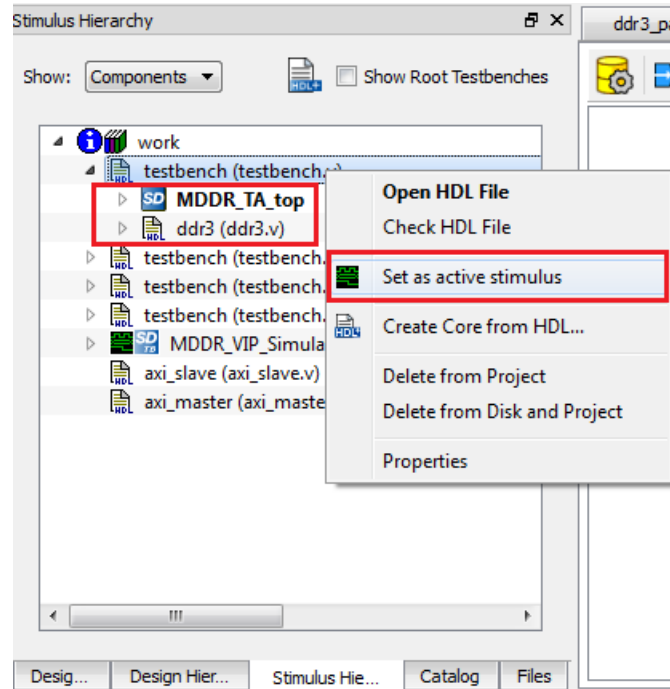
```

---

**Figure 14 • Instantiating Simulation Model**

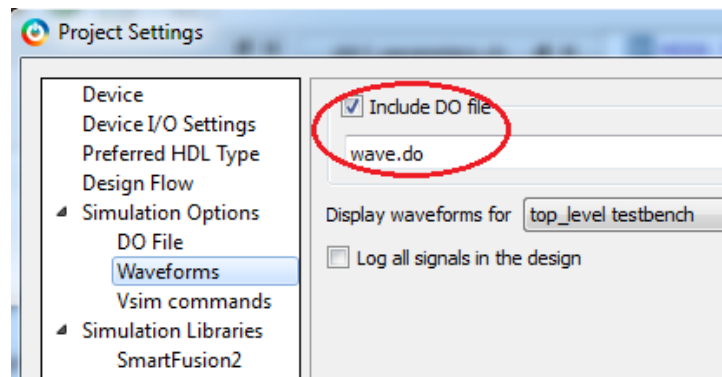
4. Ensure that the `ddr3.v` file is included at the top of the testbench file. The example design uses two instances of DDR3 models with a device width of eight.

- Set the testbench in which DDR3 memory model is instantiated as active stimulus. [Figure 15](#) shows the settings under Stimulus Hierarchy.



**Figure 15 • Stimulus Settings**

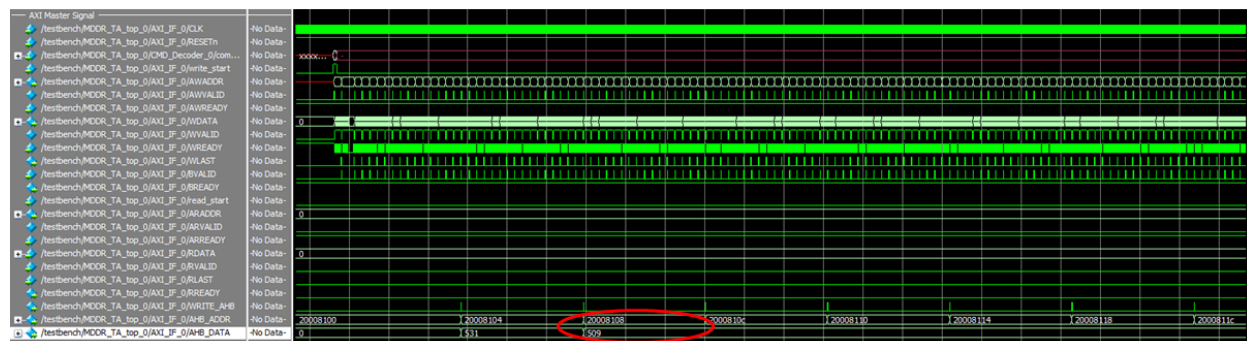
- Click **Project > Project Settings > Simulation Options > Waveforms**. [Figure 16](#) shows the Waveforms settings on the right.



**Figure 16 • Waveforms Settings**

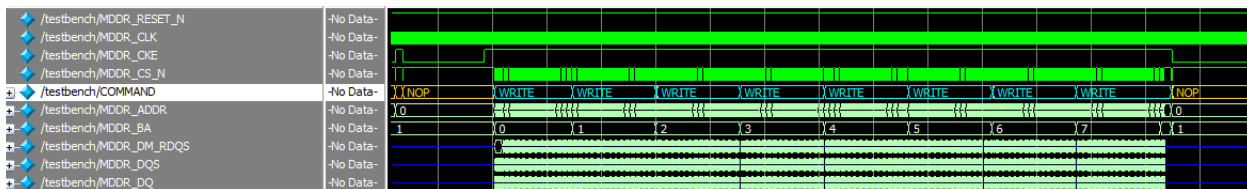
- Select the **Include DO file** check box and enter **wave.do** in the box, as displayed in [Figure 16](#).

The timing diagrams shown from Figure 17 through Figure 19 illustrate the write operation. Figure 17 shows the AXI master signals, command from CMD\_Decoder, and address and data to AHB master.



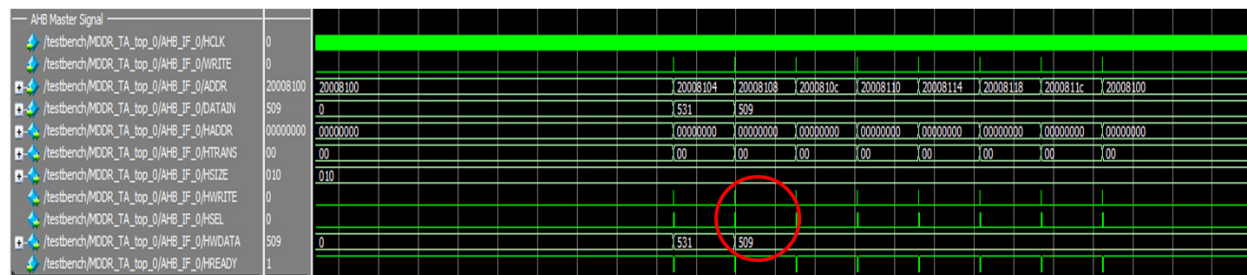
**Figure 17 • AXI Master (AXI\_IF) Signals for Write Operation**

Figure 18 shows the MDDR signals. AXI master reads 2 KB of data from LSRAM and writes to DDR3 SDRAM. The write operation is repeated eight times. The data is written into Row 0 of all banks (Bank 0 – Bank 7).



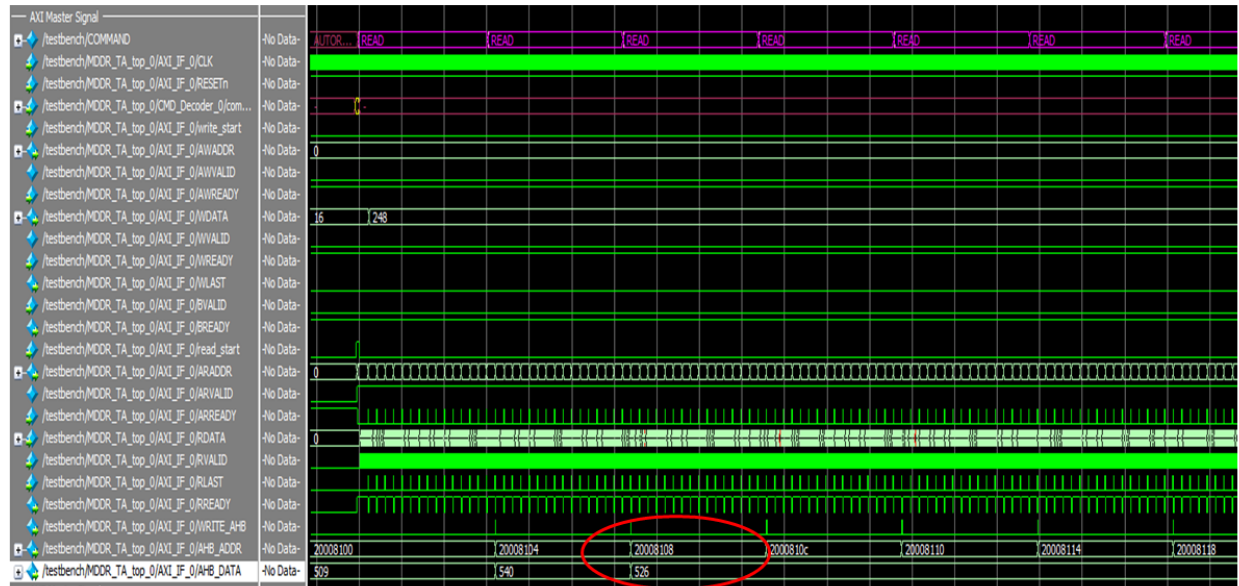
**Figure 18 • MDDR Signals for Write Operation**

Figure 19 shows the AHB master signals. AHB master receives the address and data from AXI master and writes into eSRAM.



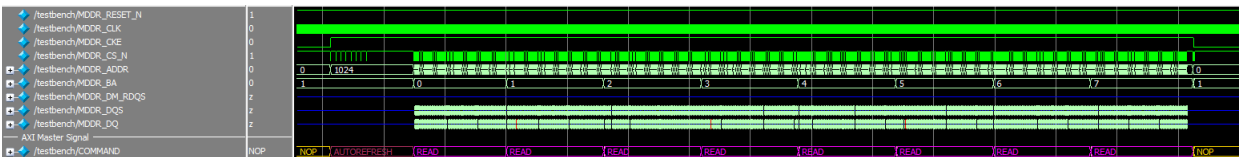
**Figure 19 • AHB Master Signals**

The timing diagrams shown from Figure 20 through Figure 22 shows the read operation. Figure 20 shows the AXI master signals, command from CMD\_Decoder, and address and data to AHB master.



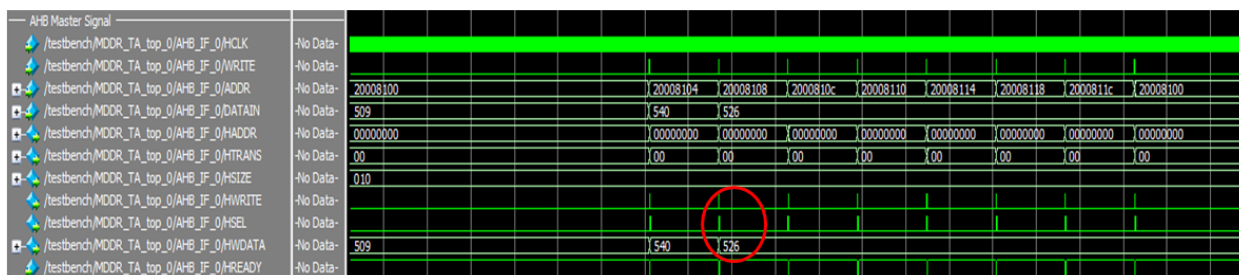
**Figure 20 • AXI Master (AXI\_IF) Signals for Read Operation**

Figure 21 shows the MDDR signals. AXI master reads 2 KB of data from DDR3 SDRAM and writes to LSRAM. The read operation is repeated eight times. The data is read from Row 0 of all banks (Bank 0 – Bank 7).



**Figure 21 • MDDR Signals for Read Operation**

Figure 22 shows the AHB master signals. AHB master receives the address and data from AXI master and writes to eSRAM.



**Figure 22 • AHB Master Signals**

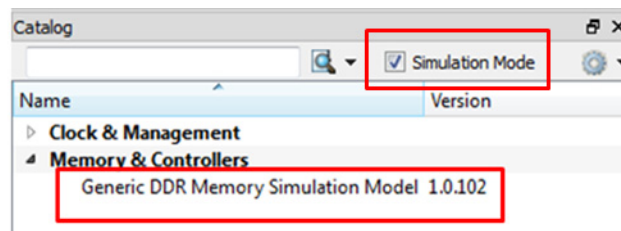
## Simulation using Microsemi DDR3 SDRAM VIP Model

Libero SoC includes a generic DDR memory simulation model (VIP). The VIP is attached to the pin side of the MDDR or FDDR subsystem, and simulates the functionality of a DDR memory device. It can be configured for DDR2, DDR3, and LPDDR SDRAM memories as well.

### Setting Up Simulation Model

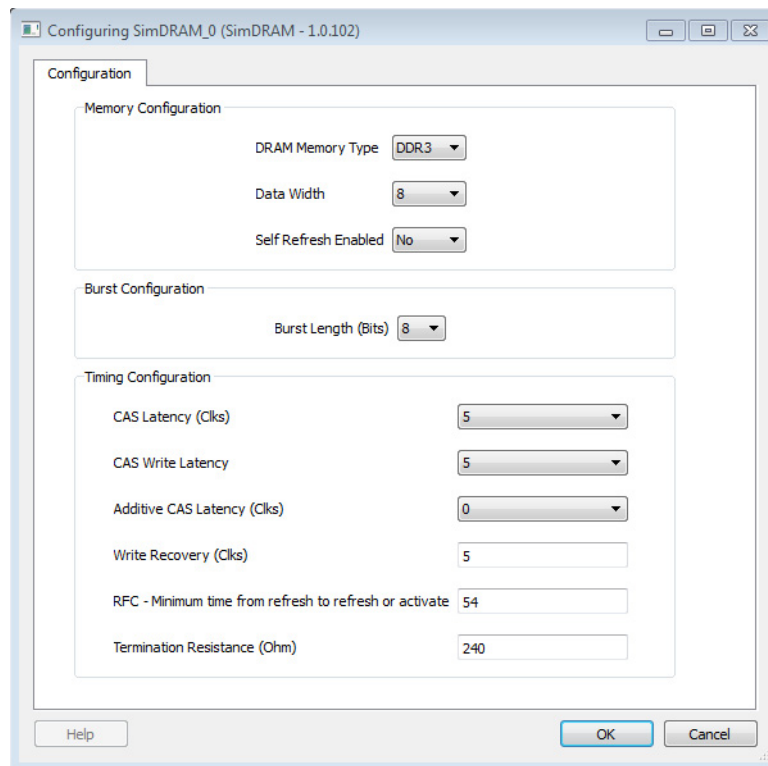
Setting up and running the simulation involve the followings steps:

1. Click **Catalog** tab in the Libero SoC.
2. Select the **Simulation Mode** check box.
3. Under **Memory and Controller**, select **Generic DDR Memory Simulation** model and drag into the SmartDesign testbench canvas. [Figure 23](#) shows the Simulation mode.



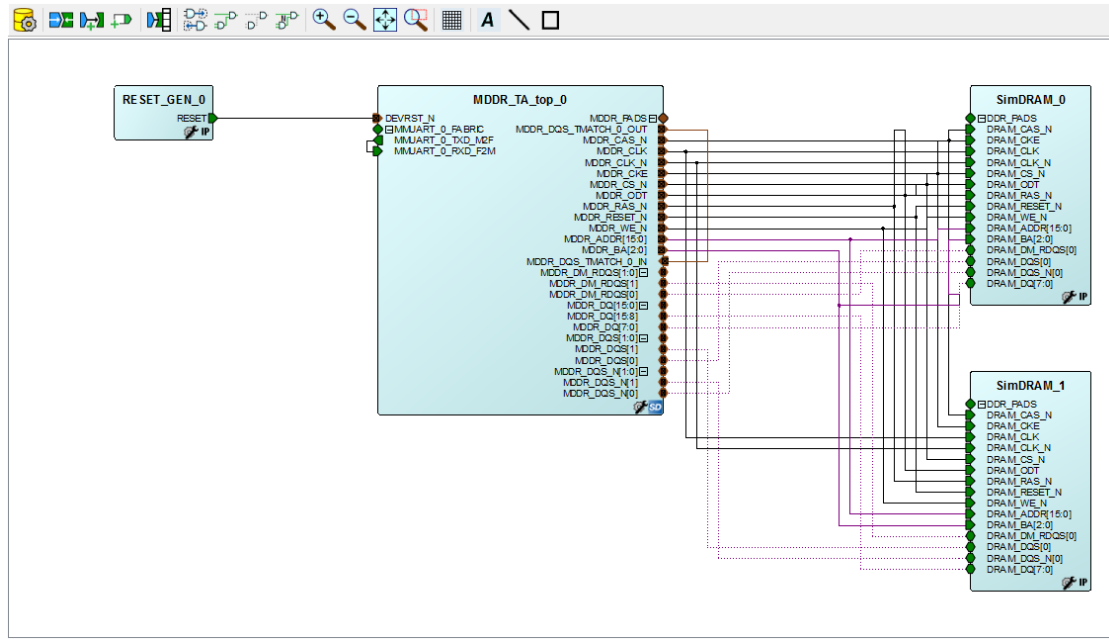
**Figure 23 • Generic DDR Memory Simulation Model**

4. Enter the Generic DDR Memory Simulation model configuration details, as shown in [Figure 24](#). The example design uses two instances of SimDRAM (VIP model) with a device width size of eight.



**Figure 24 • Configuring SimDRAM**

- Connect as described in "Simulation using Microsemi DDR3 SDRAM VIP Model" section on page 22. The connections are same as the Micron model. Figure 25 shows the SmartDesign testbench for the example design with Microsemi DDR3 SDRAM VIP model.



**Figure 25 • SmartDesign Testbench for Example Design with Microsemi DDR3 SDRAM VIP**

- Generate the design by clicking **SmartDesign > Generate Component** or by clicking **Generate Component** on the SmartDesign toolbar.
- Add the following code above **endmodule** in the generated SmartDesign testbench file, MDDR\_VIP\_Simulation.v.

```

wire [1:0] MDDR_DM_RDQS;
wire [15:0] MDDR_DQ;
wire [1:0] MDDR_DQS;
wire [2:0] COMMAND;
assign COMMAND =
{MDDR_TA_top_0_MDDR_RAS_N,MDDR_TA_top_0_MDDR_CAS_N,MDDR_TA_top_0_MDDR_WE_N};
assign MDDR_DM_RDQS = MDDR_DM_RDQS_net_0;
assign MDDR_DQ = MDDR_DQ_net_0;
assign MDDR_DQS = MDDR_DQS_net_0;
initial
begin
$display ("+++++");
$display ("Loading LSRAM from lsram.mem file");
$display ("");
$readmemh("lsram_512x64.mem",MDDR_VIP_Simulation.MDDR_TA_top_0.AXI_IF_0.Rdata_me
m);
$display (" Completed Loading LSRAM");
$display ("+++++");
@(posedge MDDR_VIP_Simulation.MDDR_TA_top_0.AXI_IF_0.RESETn);
/* 2KB write */
repeat(9500) @(posedge MDDR_VIP_Simulation.MDDR_TA_top_0.AXI_IF_0.CLK);
force MDDR_VIP_Simulation.MDDR_TA_top_0.CMD_Decoder_0.command = 8'b001_001_01;
/* Disable Write */
repeat(15) @(posedge MDDR_VIP_Simulation.MDDR_TA_top_0.AXI_IF_0.CLK);
force MDDR_VIP_Simulation.MDDR_TA_top_0.CMD_Decoder_0.command = 8'b000_000_00;
/* 2KB Read */
repeat(5000) @(posedge MDDR_VIP_Simulation.MDDR_TA_top_0.AXI_IF_0.CLK);
force MDDR_VIP_Simulation.MDDR_TA_top_0.CMD_Decoder_0.command = 8'b001_001_10;

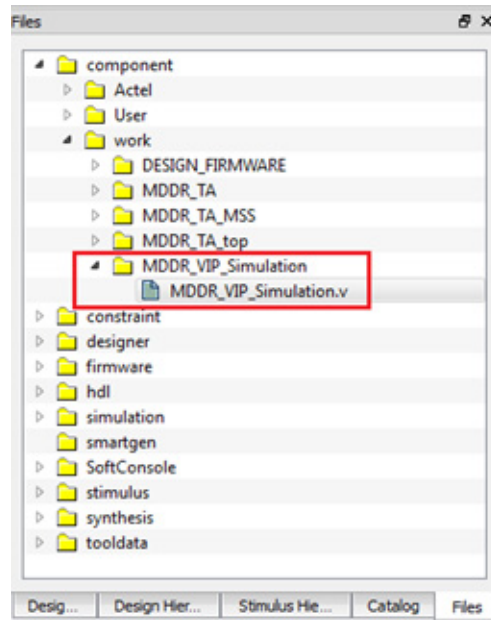
```

```

/* Disable Read */
repeat(15) @(posedge MDDR_VIP_Simulation.MDDR_TA_top_0.AXI_IF_0.CLK);
force MDDR_VIP_Simulation.MDDR_TA_top_0.CMD_Decoder_0.command = 8'b000_000_00;
end

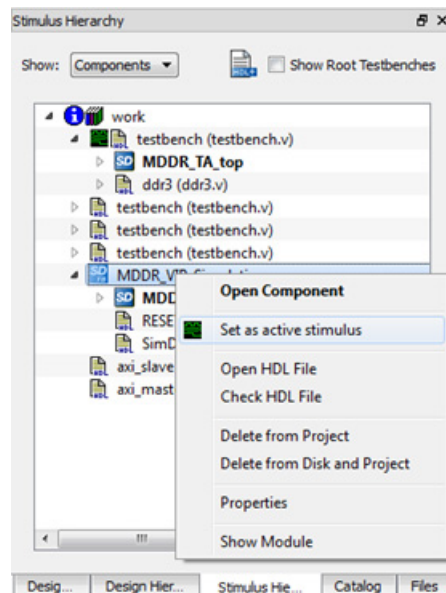
```

Figure 26 shows the SmartDesign generated testbench file under the **Files** tab.



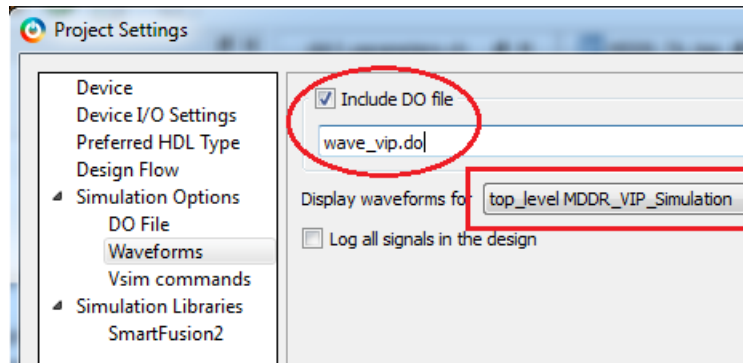
**Figure 26 • SmartDesign Generated Testbench File**

8. Under the **Stimulus Hierarchy** tab, set the SmartDesign testbench as **Set as active stimulus**.  
 Figure 27 shows the Stimulus Hierarchy settings.



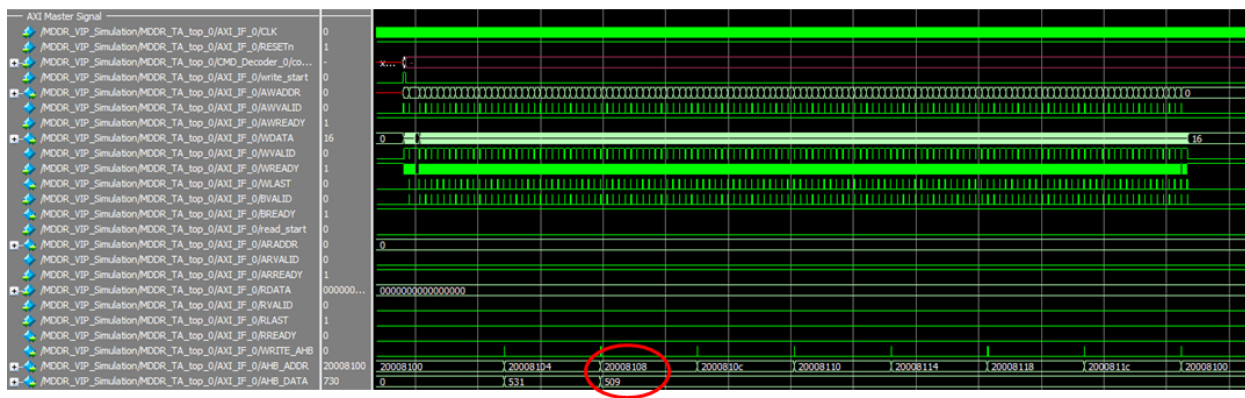
**Figure 27 • Stimulus Settings**

- Change the default DO file name to **wave\_vip.do** file in **Project > Project Settings > Simulation Options > Waveforms**. Figure 28 shows the Waveforms settings.



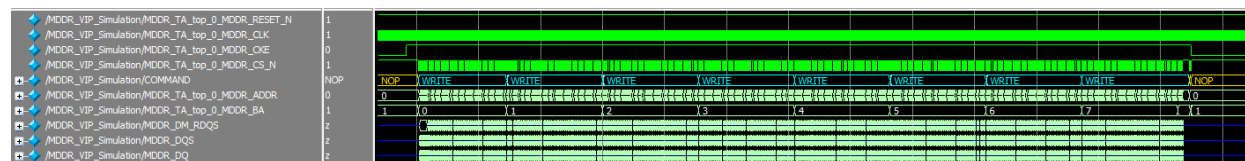
**Figure 28 • Waveforms Settings**

The timing diagrams from Figure 29 through Figure 31 on page 26 shows the write operation. Figure 29 shows the AXI master signals, command from CMD\_Decoder, and address and data to AHB master.



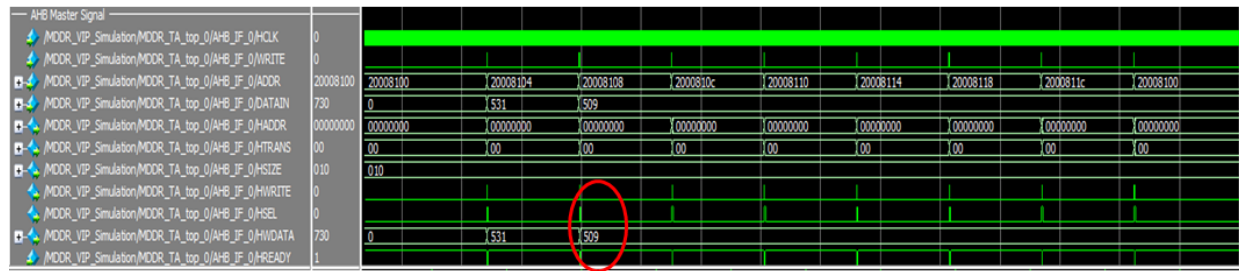
**Figure 29 • AXI Master (AXI\_IF) Signals for Write Operation**

Figure 30 shows the MDDR subsystem signals. AXI master reads 2 KB of data from LSRAM and writes into DDR3 SDRAM. The write operation is repeated eight times. The data is written into Row 0 of all banks (Bank 0 – Bank 7).



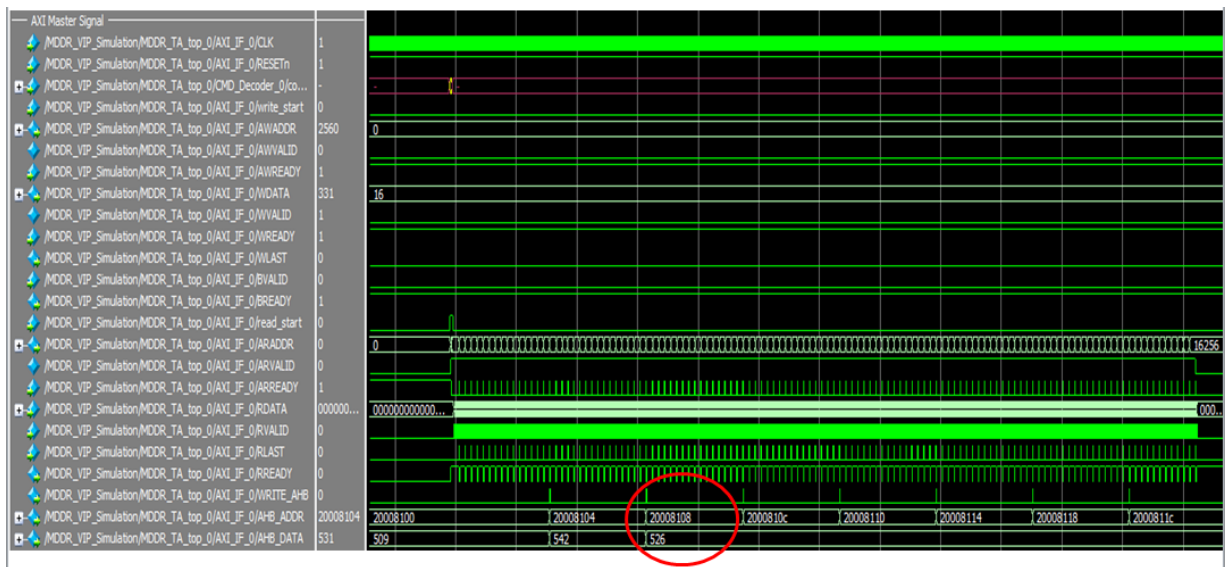
**Figure 30 • MDDR Signals for Write Operation**

Figure 31 shows the AHB master signals. AHB master receives address and data from AXI master and writes into eSRAM.



**Figure 31 • AHB Master Signals**

The timing diagrams from Figure 32 through Figure 34 on page 27 shows the read operation. Figure 32 shows the AXI master signals, command from CMD\_Decoder, and address and data to AHB master.



**Figure 32 • AXI Master (AXI\_IF) Signals for Read Operation**

Figure 33 shows the MDDR signals. AXI master reads 2 KB of data from DDR3 SDRAM and writes into LSRAM. The read operation is repeated eight times. The data is read from Row 0 of all banks (Bank 0 – Bank 7).



**Figure 33 • MDDR Signals for Read Operation**

Figure 34 shows the AHB master signals. AHB master receives address and data from AXI master and writes into eSRAM.

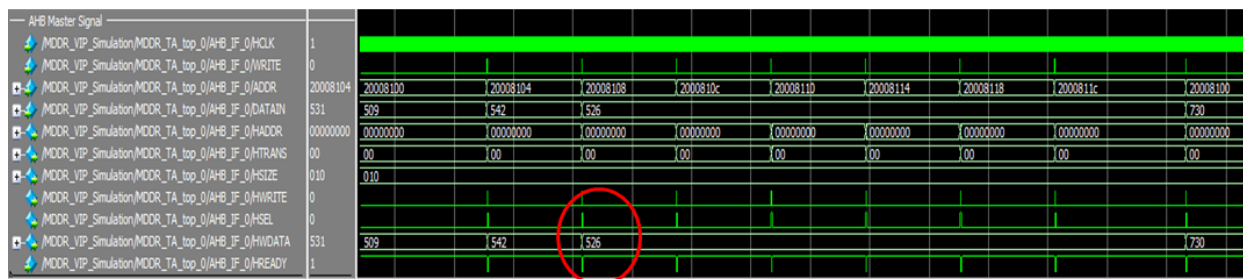


Figure 34 • AHB Master Signal

## Software Implementation

The software design example performs the following operations:

- Initializing and configuring the MMUART\_0 with 115200 baud rate, 8 data bits, 1 stop bit, no parity, and no flow control. This is done by adding MICROSEMI\_STDIO\_THRU\_MMUART0 symbol in the project settings, as shown in Figure 35.

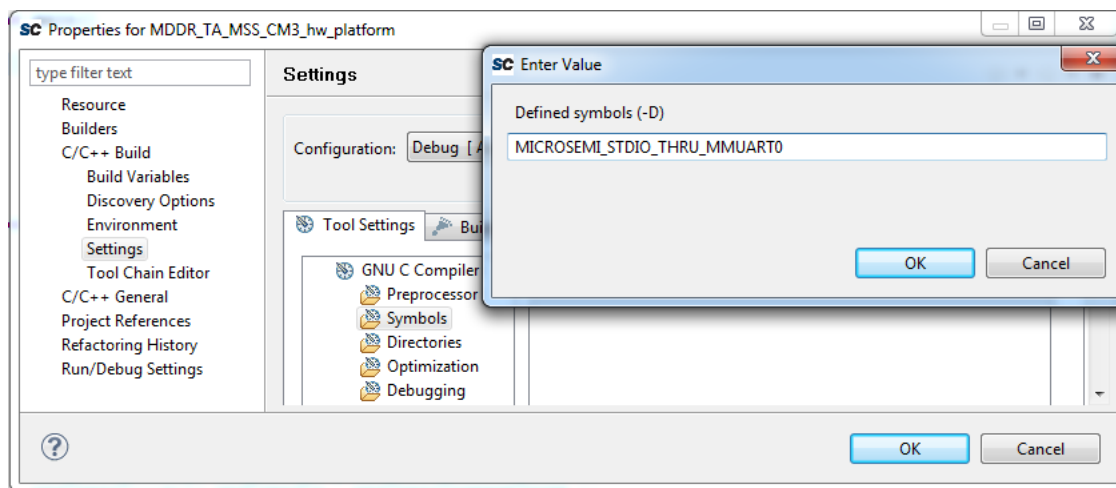


Figure 35 • MICROSEMI\_STDIO\_THRU\_MMUART0 Symbol Settings

- Initializing and configuring the GPIOs (MSS\_GPIO\_0 to MSS\_GPIO\_7 are configured in the output mode).
- Initializing the DDR3 SDRAM:
  - 16777216x4 locations, starting from address 0xA0000000, are filled with zeros.
  - 8x1024x4 locations, starting from address 0xA1000000, are filled with incremental patterns.
- Initializing the eSRAM: 8x4 locations, starting from address 0x20008104, are filled with zeros.
- Performing the data integrity checks.
- Sending a command to AXI master for reading operation through GPIOs.
- Sending a command to AXI master for writing operation through GPIOs.

List of firmware drivers used in this application:

- SmartFusion2 MSS GPIO driver
- SmartFusion2 MSS MMUART driver: to communicate with the serial terminal program running on the host PC

In this design example, the application software performs the following steps:

1. Performing the following data integrity checks:
  - a. The Cortex-M3 processor initializes the 8x1024x4 (8 repetitions x 1024 locations x 4 bytes) locations of DDR3 SDRAM, starting from address 0xA1000000, with incremental patterns. The pattern increments from 0 to 1023, and is repeated eight times.
  - b. AXI master reads 4 KB of data from DDR3 SDRAM, starting from the address 0x01000000, that is, 0xA1000000<sup>1</sup>, and writes into LSRAM. The read operation is repeated eight times. The last 4 KB of data is fetched from the address 0x01007000, that is, 0xA1007000<sup>1</sup>.
  - c. AXI master reads 4 KB of data from LSRAM (512x64) and writes into DDR3 SDRAM, starting from address 0x00000000, that is, 0xA0000000<sup>1</sup>. The write operation is repeated eight times. The last 4 KB of data is written at the address 0x00007000, that is, 0xA0007000.
  - d. The Cortex-M3 processor compares the 4 KB data at address 0xA0007000 and 0xA1007000. The status is printed on HyperTerminal with error count, if any.

**Note:** The address map to access the DDR memory from MSS masters through MDDR is 0xA0000000-0xDFFFFFFF.

2. Initializing the DDR3 SDRAM again.
3. Perform the read operation. Uncomment any of the following lines based on the size of data to be read from DDR3 SDRAM. The default size is 2 KB.

```

/* DDR3 SDRAM READ OPERATION
 * Performing the read operation. Uncomment the any of the following lines
 * based on the size of the data to be read from DDR3 SDRAM. The default size is 2KB*/

//MSS_GPIO_set_outputs(0x26); // 2KB
//delay(50); // 2KB
//MSS_GPIO_set_outputs(0x24); // 2KB

//MSS_GPIO_set_outputs(0x4A); // 4KB
//delay(50); // 4KB
//MSS_GPIO_set_outputs(0x48); // 4KB

//MSS_GPIO_set_outputs(0x6E); // 8KB
//delay(50); // 8KB
//MSS_GPIO_set_outputs(0x6C); // 8KB

//MSS_GPIO_set_outputs(0x92); // 16KB
//delay(50); // 16KB
//MSS_GPIO_set_outputs(0x90); // 16KB

```

4. Printing the read throughput values on HyperTerminal.

- Performing the write operation. Uncomment any of the following lines based on the size of data to be written into DDR3 SDRAM. The default size is 2 KB.

```

/* DDR3 SDRAM WRITE OPERATION
 * Performing the write operation. Uncomment the any of the following lines based on
 * the size of the data to be written into DDR3 SDRAM. The default size is 2KB */

//MSS_GPIO_set_outputs(0x25); // 2KB
//delay(50); // 2KB
//MSS_GPIO_set_outputs(0x24); // 2KB

//MSS_GPIO_set_outputs(0x49); // 4KB
//delay(50); // 4KB
//MSS_GPIO_set_outputs(0x48); // 4KB

//MSS_GPIO_set_outputs(0x6D); // 8KB
//delay(50); // 8KB
//MSS_GPIO_set_outputs(0x6C); // 8KB

//MSS_GPIO_set_outputs(0x91); // 16KB
//delay(50); // 16KB
//MSS_GPIO_set_outputs(0x90); // 16KB

```

- Printing the write throughput values on HyperTerminal.

## Running the Design

The design example is designed to run on the SmartFusion2 Advanced Development Kit board. For more information about the kit board, see <http://www.microsemi.com/products/fpga-soc/design-resources/dev-kits/smartfusion2/smartfusion2-advanced-development-kit>.

### Board Jumper Settings

Table 5 lists the jumpers that need to be connected on SmartFusion2 Advanced Development Kit board.

**Table 5 • SmartFusion2 Advanced Development Kit Jumper Settings**

| Jumper                | Pin (From) | Pin (To) | Comments                                                                                                                    |
|-----------------------|------------|----------|-----------------------------------------------------------------------------------------------------------------------------|
| J116, J353, J354, J54 | 1          | 2        | These are the default jumper settings of the Advanced Development Kit Board. Ensure that these jumpers are set accordingly. |
| J123                  | 2          | 3        |                                                                                                                             |
| J124, J121, J32       | 1          | 2        | JTAG programming via FTDI                                                                                                   |

**Note:** Switch OFF the power switch, **SW7**, while connecting the jumpers.

### Host PC to Board Connections

- Connect the FlashPro4 programmer to the FP4 HEADER J37 connector of the SmartFusion2 Advanced Development Kit board.
- Connect the J33 connector on the SmartFusion2 Advanced Development Kit board to the host PC using the USB mini-B (FTDI interface) cable.

## USB Driver Installation

Install the FTDI D2XX driver for serial terminal communication through the FTDI mini USB cable. The drivers and installation guide can be downloaded from [www.microsemi.com/soc/documents/CDM\\_2.08.24\\_WHQL\\_Certified.zip](http://www.microsemi.com/soc/documents/CDM_2.08.24_WHQL_Certified.zip).

Ensure that the USB to UART bridge drivers are detected by verifying the Device Manager, as shown in Figure 36 on page 30.

**Note:** Copy the COM port number for serial port configuration. Ensure that the COM port **Location** is specified as **on USB Serial Converter C**, as shown in Figure 36.

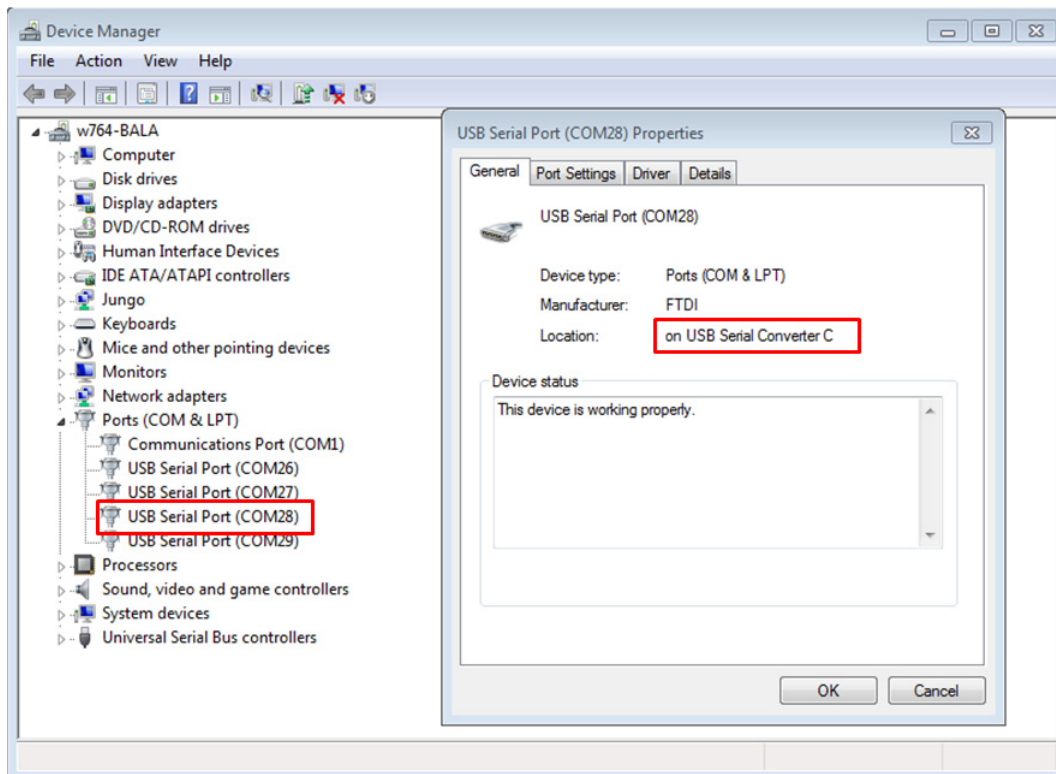
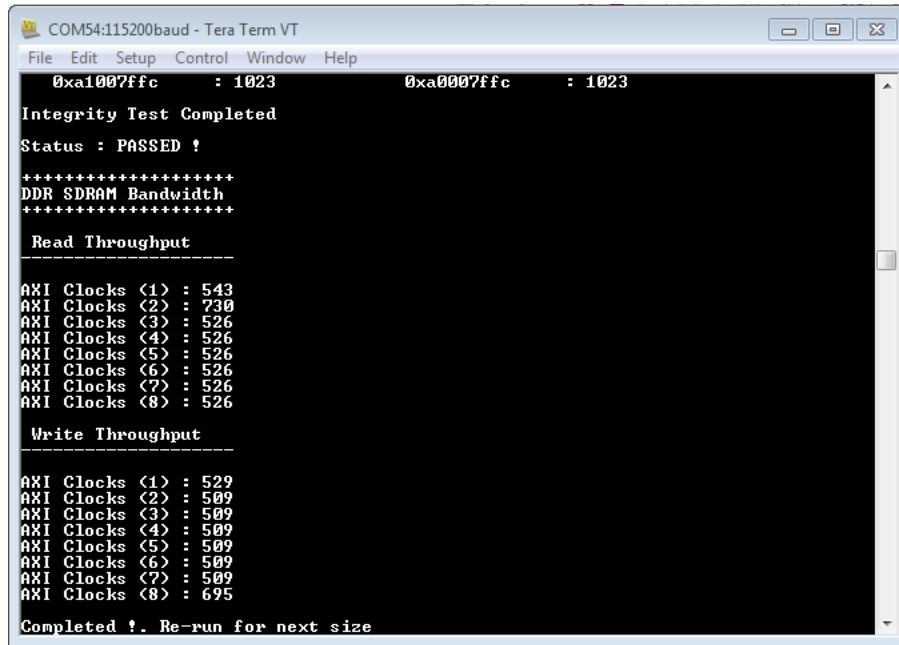


Figure 36 • USB to UART Bridge Drivers

## Steps to Run the Design

1. Connect the power supply to the J42 connector and FlashPro programmer.
2. Switch ON the power supply switch, **SW7**.
3. Program the SmartFusion2 Advanced Development Kit board with the generated or provided \*.stp file (See "Appendix: Design Files" on page 36) using FlashPro.
4. Invoke the SoftConsole v3.4 integrated design environment (IDE) and launch the debugger.
5. Start the HyperTerminal program with the baud rate set to 115200, 8 data bits, 1 stop bit, no parity, and no flow control. If the PC does not have HyperTerminal, use any free serial terminal emulation program, such as PuTTY or TeraTerm. See the [Configuring Serial Terminal Emulation Programs Tutorial](#), for configuring HyperTerminal, TeraTerm, and PuTTY.

When the debugger runs in SoftConsole, the HyperTerminal window is displayed with the data integrity check-status followed by the read and write throughputs. [Figure 37](#) shows the total number of AXI clocks used for 2 KB of data transferred from LSRAM to DDR3 SDRAM and DDR3 SDRAM to LSRAM.



```

COM54:115200baud - Tera Term VT
File Edit Setup Control Window Help
0xa1007ffc : 1023 0xa0007ffc : 1023

Integrity Test Completed
Status : PASSED !

+++++
DDR SDRAM Bandwidth
+++++

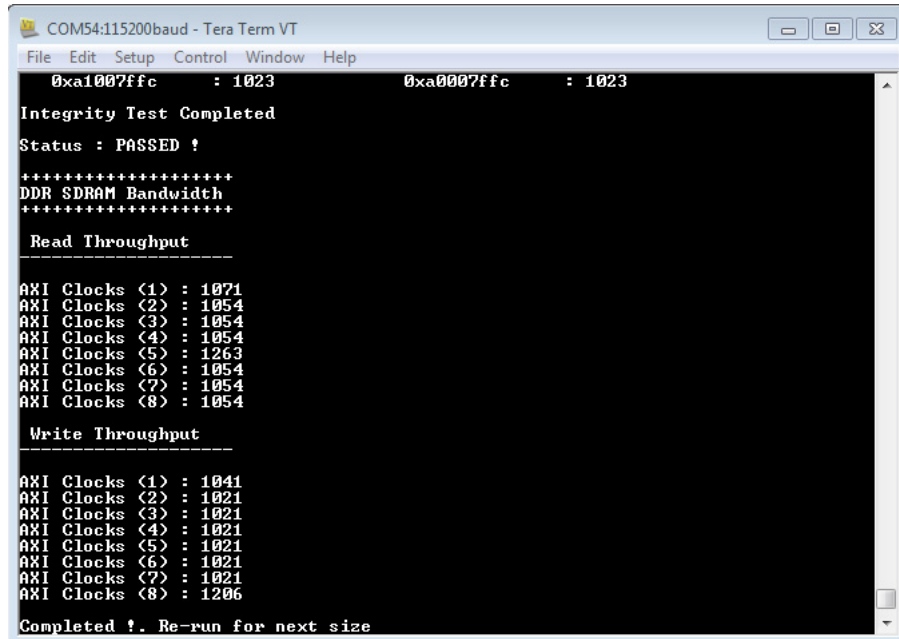
Read Throughput
-----
AXI Clocks (1) : 543
AXI Clocks (2) : 730
AXI Clocks (3) : 526
AXI Clocks (4) : 526
AXI Clocks (5) : 526
AXI Clocks (6) : 526
AXI Clocks (7) : 526
AXI Clocks (8) : 526

Write Throughput
-----
AXI Clocks (1) : 529
AXI Clocks (2) : 509
AXI Clocks (3) : 509
AXI Clocks (4) : 509
AXI Clocks (5) : 509
AXI Clocks (6) : 509
AXI Clocks (7) : 509
AXI Clocks (8) : 695

Completed !. Re-run for next size
  
```

**Figure 37 • Throughput for 2 KB Data**

[Figure 38](#) shows the total number of AXI clocks used for 4 KB of data transferred from LSRAM to DDR3 SDRAM and DDR3 SDRAM to LSRAM.



```

COM54:115200baud - Tera Term VT
File Edit Setup Control Window Help
0xa1007ffc : 1023 0xa0007ffc : 1023

Integrity Test Completed
Status : PASSED !

+++++
DDR SDRAM Bandwidth
+++++

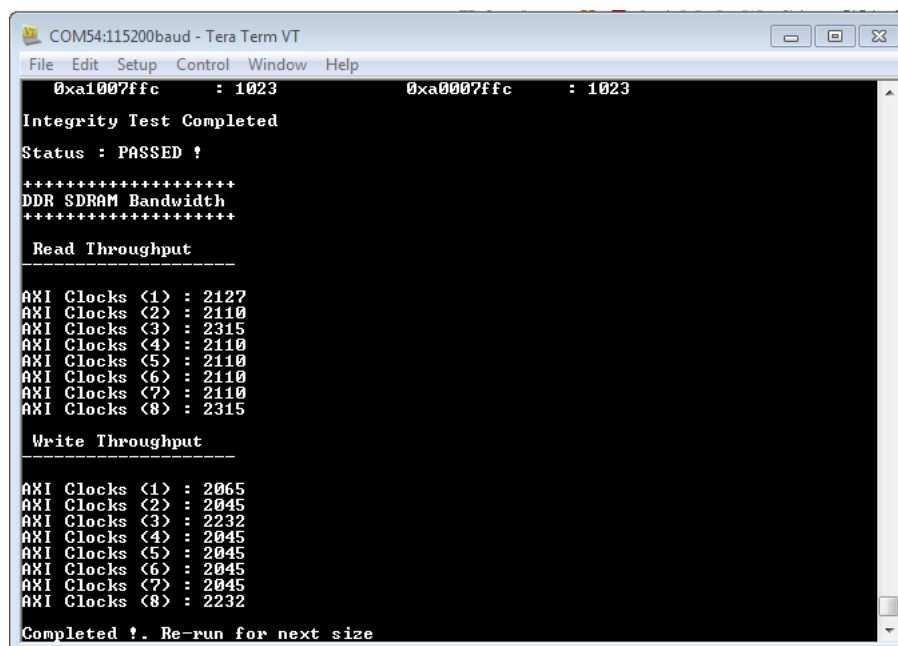
Read Throughput
-----
AXI Clocks (1) : 1071
AXI Clocks (2) : 1054
AXI Clocks (3) : 1054
AXI Clocks (4) : 1054
AXI Clocks (5) : 1263
AXI Clocks (6) : 1054
AXI Clocks (7) : 1054
AXI Clocks (8) : 1054

Write Throughput
-----
AXI Clocks (1) : 1041
AXI Clocks (2) : 1021
AXI Clocks (3) : 1021
AXI Clocks (4) : 1021
AXI Clocks (5) : 1021
AXI Clocks (6) : 1021
AXI Clocks (7) : 1021
AXI Clocks (8) : 1206

Completed !. Re-run for next size
  
```

**Figure 38 • Throughput for 4 KB Data**

Figure 39 shows the total number of AXI clocks used for 8 KB of data transferred from LSRAM to DDR3 SDRAM and DDR3 SDRAM to LSRAM.



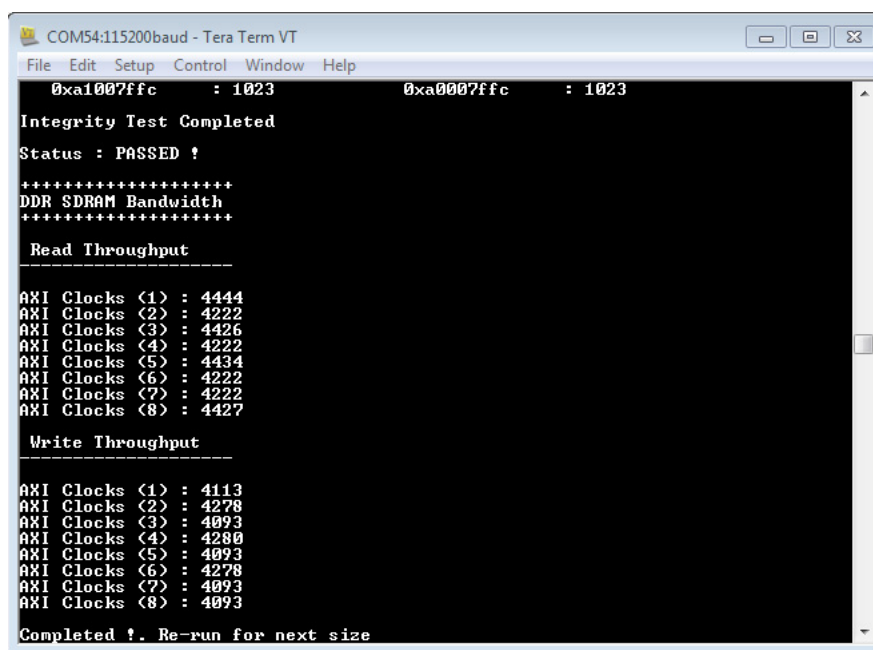
```

COM54:115200baud - Tera Term VT
File Edit Setup Control Window Help
0xa1007ffc : 1023 0xa0007ffc : 1023
Integrity Test Completed
Status : PASSED !
*****
DDR SDRAM Bandwidth
*****
Read Throughput
-----
AXI Clocks (1) : 2127
AXI Clocks (2) : 2110
AXI Clocks (3) : 2315
AXI Clocks (4) : 2110
AXI Clocks (5) : 2110
AXI Clocks (6) : 2110
AXI Clocks (7) : 2110
AXI Clocks (8) : 2315
Write Throughput
-----
AXI Clocks (1) : 2065
AXI Clocks (2) : 2045
AXI Clocks (3) : 2232
AXI Clocks (4) : 2045
AXI Clocks (5) : 2045
AXI Clocks (6) : 2045
AXI Clocks (7) : 2045
AXI Clocks (8) : 2232
Completed !. Re-run for next size

```

**Figure 39 • Throughput for 8 KB Data**

Figure 40 shows the total number of AXI clocks used for 16 KB of data transferred from LSRAM to DDR3 SDRAM and DDR3 SDRAM to LSRAM.



```

COM54:115200baud - Tera Term VT
File Edit Setup Control Window Help
0xa1007ffc : 1023 0xa0007ffc : 1023
Integrity Test Completed
Status : PASSED !
*****
DDR SDRAM Bandwidth
*****
Read Throughput
-----
AXI Clocks (1) : 4444
AXI Clocks (2) : 4222
AXI Clocks (3) : 4426
AXI Clocks (4) : 4222
AXI Clocks (5) : 4434
AXI Clocks (6) : 4222
AXI Clocks (7) : 4222
AXI Clocks (8) : 4427
Write Throughput
-----
AXI Clocks (1) : 4113
AXI Clocks (2) : 4278
AXI Clocks (3) : 4093
AXI Clocks (4) : 4280
AXI Clocks (5) : 4093
AXI Clocks (6) : 4278
AXI Clocks (7) : 4093
AXI Clocks (8) : 4093
Completed !. Re-run for next size

```

**Figure 40 • Throughput for 16 KB Data**

## DDR3 SDRAM Bandwidth

Table 6 provides the total number of 16-beat bursts corresponding to the write or read size.

**Table 6 • Total Number of 16 Beat Bursts**

| Write or Read Data Size | Total Number of 16 Beat Bursts |
|-------------------------|--------------------------------|
| 2 KB                    | 16                             |
| 4 KB                    | 32                             |
| 8 KB                    | 64                             |
| 16 KB                   | 128                            |

The following equation is applied to calculate the throughput:

$$\text{Bandwidth (MB/s)} = (16 \div (\text{Total number of AXI clocks} \div \text{Total number of 16 beat bursts})) \times 8 \times \text{AXI clock (MHz)}$$

EQ 1

## Simulation Result

Table 7 lists the write and read bandwidths of DDR3 SDRAM simulation. The incremental pattern of size varies from 2 KB to 16 KB, which is transferred from LSRAM to DDR3 SDRAM and DDR3 SDRAM to LSRAM.

**Table 7 • DDR3 SDRAM Bandwidth - Simulation Result**

| SI No | Optimization Techniques                                                                    | Size (KB) | Write            |                    | Read             |                    | Write Improvement (Average) | Read Improvement (Average) |
|-------|--------------------------------------------------------------------------------------------|-----------|------------------|--------------------|------------------|--------------------|-----------------------------|----------------------------|
|       |                                                                                            |           | Number of Cycles | Bandwidth (MB/Sec) | Number of Cycles | Bandwidth (MB/Sec) |                             |                            |
| Base  | 160 MHz                                                                                    | 2         | 539              | 607                | 737              | 445                | 605                         | 448                        |
|       |                                                                                            | 4         | 1083             | 605                | 1476             | 444                |                             |                            |
|       |                                                                                            | 8         | 2171             | 604                | 2954             | 443                |                             |                            |
|       |                                                                                            | 16        | 4347             | 603                | 5921             | 442                |                             |                            |
| 1     | 166 MHz                                                                                    | 2         | 539              | 631                | 737              | 461                | 627.5<br>3.7%               | 461<br>2.8%                |
|       |                                                                                            | 4         | 1083             | 628                | 1476             | 461                |                             |                            |
|       |                                                                                            | 8         | 2171             | 626                | 2954             | 460                |                             |                            |
|       |                                                                                            | 16        | 4347             | 625                | 5913             | 460                |                             |                            |
| 2     | 166 MHz<br>Without Write Response State                                                    | 2         | 509              | 668                | 737              | 461                | 666<br>6.13%                | 461<br>2.8%                |
|       |                                                                                            | 4         | 1021             | 666                | 1476             | 461                |                             |                            |
|       |                                                                                            | 8         | 2045             | 665                | 2954             | 460                |                             |                            |
|       |                                                                                            | 16        | 4093             | 664                | 5913             | 460                |                             |                            |
| 3     | 166 MHz<br>Without Write Response State<br>Tuned DDR Configuration                         | 2         | 509              | 668                | 736              | 462                | 666<br>6.13%                | 461<br>2.8%                |
|       |                                                                                            | 4         | 1021             | 666                | 1474             | 461                |                             |                            |
|       |                                                                                            | 8         | 2045             | 665                | 2950             | 461                |                             |                            |
|       |                                                                                            | 16        | 4093             | 664                | 5910             | 460                |                             |                            |
| 4     | 166 MHz<br>Without Write Response State<br>Tuned DDR Configuration<br>Read Command Queuing | 2         | 509              | 668                | 526              | 646                | 666<br>6.13%                | 645<br>39.9%               |
|       |                                                                                            | 4         | 1021             | 666                | 1054             | 645                |                             |                            |
|       |                                                                                            | 8         | 2045             | 665                | 2110             | 644                |                             |                            |
|       |                                                                                            | 16        | 4093             | 664                | 4222             | 644                |                             |                            |

## Board Test Result

Table 8 lists the write and read bandwidth of DDR3 SDRAM on SmartFusion2 Advanced Development Kit board. The incremental pattern of size varies from 2 KB to 16 KB, which is transferred from LSRAM to DDR3 SDRAM and DDR3 SDRAM to LSRAM.

**Table 8 • DDR3 SDRAM Bandwidth - Board Test Result**

| SI No | Optimization Techniques                                                                      | Size (KB) | Write            |                    | Read             |                    | Write Improvement (Average) | Read Improvement (Average) |       |
|-------|----------------------------------------------------------------------------------------------|-----------|------------------|--------------------|------------------|--------------------|-----------------------------|----------------------------|-------|
|       |                                                                                              |           | Number of Cycles | Bandwidth (MB/Sec) | Number of Cycles | Bandwidth (MB/Sec) |                             |                            |       |
| Base  | 160 Mhz                                                                                      | 2         | 539              | 607                | 737              | 445                | 605                         | 448                        |       |
|       |                                                                                              | 4         | 1083             | 605                | 1476             | 444                |                             |                            |       |
|       |                                                                                              | 8         | 2171             | 604                | 2954             | 443                |                             |                            |       |
|       |                                                                                              | 16        | 4347             | 603                | 5913             | 460                |                             |                            |       |
| 1     | 166.6 Mhz                                                                                    | 2         | 539              | 631                | 736              | 461                | 627.5 3.7%                  | 461                        | 2.8%  |
|       |                                                                                              | 4         | 1083             | 628                | 1474             | 461                |                             |                            |       |
|       |                                                                                              | 8         | 2171             | 626                | 2950             | 461                |                             |                            |       |
|       |                                                                                              | 16        | 4347             | 625                | 5924             | 460                |                             |                            |       |
| 2     | 166.6 Mhz<br>Without Write Response State                                                    | 2         | 509              | 668                | 736              | 461                | 666 6.13%                   | 461                        | 2.8%  |
|       |                                                                                              | 4         | 1021             | 666                | 1477             | 461                |                             |                            |       |
|       |                                                                                              | 8         | 2045             | 665                | 2959             | 461                |                             |                            |       |
|       |                                                                                              | 16        | 4093             | 664                | 5923             | 459                |                             |                            |       |
| 3     | 166.6 Mhz<br>Without Write Response State<br>Tuned DDR Configuration                         | 2         | 509              | 668                | 736              | 462                | 666 6.13%                   | 461                        | 2.8%  |
|       |                                                                                              | 4         | 1021             | 666                | 1474             | 461                |                             |                            |       |
|       |                                                                                              | 8         | 2045             | 665                | 2953             | 461                |                             |                            |       |
|       |                                                                                              | 16        | 4093             | 664                | 5918             | 460                |                             |                            |       |
| 4     | 166.6 MHz<br>Without Write Response State<br>Tuned DDR Configuration<br>Read Command Queuing | 2         | 509              | 668                | 526              | 646                | 666 6.13%                   | 645                        | 39.9% |
|       |                                                                                              | 4         | 1021             | 666                | 1054             | 645                |                             |                            |       |
|       |                                                                                              | 8         | 2045             | 665                | 2110             | 644                |                             |                            |       |
|       |                                                                                              | 16        | 4093             | 664                | 4222             | 644                |                             |                            |       |

## Conclusion

This application note describes the DDR SDRAM bandwidth optimization techniques with an example design on the SmartFusion2 Advanced Development Kit board. It also shows the DDR SDRAM simulation flow using the Micron DDR3 SDRAM model and the Microsemi DDR3 SDRAM VIP model.

## Appendix: Design Files

The design files can be downloaded from the Microsemi website:

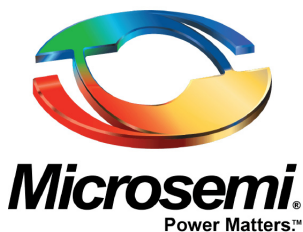
[http://soc.microsemi.com/download/rsc/?f=m2s\\_ac422\\_liberov11p7\\_df](http://soc.microsemi.com/download/rsc/?f=m2s_ac422_liberov11p7_df)

The design file consists Libero SoC Verilog project, SoftConsole software project, MDDR Configuration files, Simulation model files, and programming files (\*.stp) for the SmartFusion2 Advanced Development Kit board. See the `Readme.txt` file included in the design file for the directory structure and description.

## List of Changes

The following table shows the important changes made in this document for each revision.

| Revision                     | Changes                                                                 | Page |
|------------------------------|-------------------------------------------------------------------------|------|
| Revision 6<br>(April 2016)   | Updated the document for Libero SoC v11.7 software release (SAR 78130). | NA   |
| Revision 5<br>(October 2015) | Updated the document for Libero SoC v11.6 software release (SAR 72584). | NA   |
| Revision 4<br>(May, 2015)    | Updated the document for Libero SoC v11.5 software release (SAR 67501). | NA   |
| Revision 3<br>(August, 2014) | Rearranged a few sections. No change in content.                        | NA   |
| Revision 2<br>(August, 2014) | Updated the document for Libero SoC v11.4 software release (SAR 59944). | NA   |
| Revision 1<br>(June, 2014)   | Initial release.                                                        | NA   |



**Microsemi Corporate Headquarters**  
One Enterprise, Aliso Viejo,  
CA 92656 USA

**Within the USA:** +1 (800) 713-4113  
**Outside the USA:** +1 (949) 380-6100  
**Sales:** +1 (949) 380-6136  
**Fax:** +1 (949) 215-4996

**E-mail:** [sales.support@microsemi.com](mailto:sales.support@microsemi.com)

© 2016 Microsemi Corporation. All rights reserved. Microsemi and the Microsemi logo are trademarks of Microsemi Corporation. All other trademarks and service marks are the property of their respective owners.

Microsemi Corporation (Nasdaq: MSCC) offers a comprehensive portfolio of semiconductor and system solutions for communications, defense & security, aerospace and industrial markets. Products include high-performance and radiation-hardened analog mixed-signal integrated circuits, FPGAs, SoCs and ASICs; power management products; timing and synchronization devices and precise time solutions, setting the world's standard for time; voice processing devices; RF solutions; discrete components; enterprise storage and communication solutions, security technologies and scalable anti-tamper products; Ethernet solutions; Power-over-Ethernet ICs and midspans; as well as custom design capabilities and services. Microsemi is headquartered in Aliso Viejo, Calif., and has approximately 4,800 employees globally. Learn more at [www.microsemi.com](http://www.microsemi.com).

Microsemi makes no warranty, representation, or guarantee regarding the information contained herein or the suitability of its products and services for any particular purpose, nor does Microsemi assume any liability whatsoever arising out of the application or use of any product or circuit. The products sold hereunder and any other products sold by Microsemi have been subject to limited testing and should not be used in conjunction with mission-critical equipment or applications. Any performance specifications are believed to be reliable but are not verified, and Buyer must conduct and complete all performance and other testing of the products, alone and together with, or installed in, any end-products. Buyer shall not rely on any data and performance specifications or parameters provided by Microsemi. It is the Buyer's responsibility to independently determine suitability of any products and to test and verify the same. The information provided by Microsemi hereunder is provided "as is, where is" and with all faults, and the entire risk associated with such information is entirely with the Buyer. Microsemi does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other IP rights, whether with regard to such information itself or anything described by such information. Information provided in this document is proprietary to Microsemi, and Microsemi reserves the right to make any changes to the information in this document or to any products and services at any time without notice.